# Advanced Battery Management PMIC with Ultra Low Power Buck and Buck Boost

# **Data Sheet**

ANALOG DEVICES

# ADP5360

# **FEATURES**

Linear battery charger High accuracy and programmable charge terminal voltage and charge current up to 320 mA Compliant with JEITA charge temperature specification Li-Ion and Li-Poly battery monitor and protection Voltage-based fuel gauge with adaptive filter limitation Independent battery protection of overcharge and overdischarge **Temperature sensor with external NTC** Ultralow guiescent current buck converter Quick output discharge option Ultralow guiescent current buck boost converter Quick output discharge option Supervisory with manual reset (MR) and watchdog timer Shipment mode extends battery life Full I<sup>2</sup>C programmability with dedicated interrupt pin

# APPLICATIONS

Rechargeable Li-Ion/Li-Poly battery-powered devices Portable consumer devices Portable medical devices Wearable devices

# **GENERAL DESCRIPTION**

The ADP5360 combines one high performance linear charger for a single lithium-ion (Li-Ion)/lithium-polymer (Li-Poly) battery with a programmable, ultralow quiescent current fuel gauge and battery protection circuit, one ultralow quiescent buck, one buck boost switching regulator, and a supervisory circuit that can monitor output voltage.

The ADP5360 charger operates at up to 6.8 V to prevent USB bus spiking during disconnect or connect scenarios.

The ADP5360 features an internal isolation field effect transistor (FET) between the linear charger output and the battery node. The full battery protection features are activated when the device is in the battery overcharge and overdischarge fault conditions.

The ADP5360 fuel gauge uses a voltage-based algorithm with an adaptive filter limitation solution. The fuel gauge reports real-time battery state of charge (SOC) for the rechargeable Li-Ion battery with ultralow quiescent current.

The ADP5360 buck regulator operates at 1.0 MHz switching frequency in forced pulse-width modulation (FPWM) mode. In hysteresis mode, the regulator achieves excellent efficiency at a low output power.

The ADP5360 buck boost regulator only operates in hysteresis mode and outputs a voltage less than or greater than the battery voltage.

The ADP5360 supervisory circuits monitor the regulator output voltage and provide a power-on reset signal to the system. A watchdog timer and an external pushbutton can reset the microprocessor.

The I<sup>2</sup>C-compatible interface enables the programmability of all battery charging parameters, the protection threshold, the buck output voltage, and the status bit readback.

The ADP5360 operates over the  $-40^{\circ}$ C to  $+85^{\circ}$ C junction temperature range and is available in a 32-ball, 2.56 mm × 2.56 mm wafer level chip scale package (WLCSP).

#### Rev. 0

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11/2019—Revision 0: Initial Version

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# FUNCTIONAL BLOCK DIAGRAM

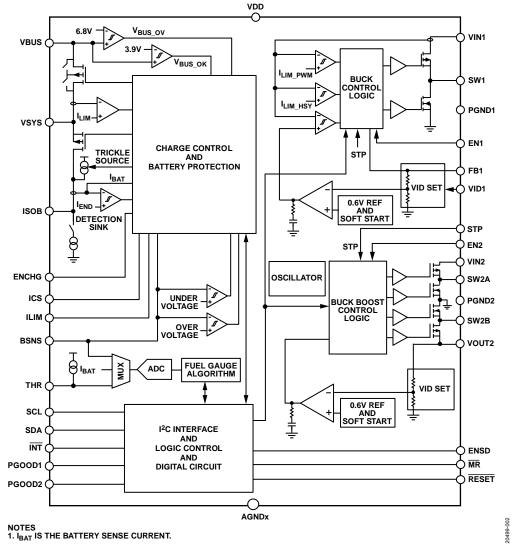


Figure 1.

# SPECIFICATIONS BATTERY CHARGER SPECIFICATIONS

 $T_J = -40^{\circ}$ C to +85°C, voltage of the VBUS pin ( $V_{VBUS}$ ) = 5.0 V, voltage of the ISOB pin ( $V_{ISOB}$ ) = 3.8 V, C1 = 2.2  $\mu$ F, C2 = 1  $\mu$ F, C3 = C4 = 10  $\mu$ F (see Figure 60), and all registers are at default values, unless otherwise noted.

Table 1.

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Max	Unit
GENERAL PARAMETERS						
Undervoltage Lockout (UVLO)	Vuvlo	Rising threshold, voltage of the ISOB pin, $V_{\text{VBUS}} = 0 \text{ V}$		2.1	2.15	V
		Falling threshold, voltage of the ISOB pin, $V_{VBUS} = 0 V$	1.8	1.88		v
Input Current Limit	ILIM	I <sub>LIM</sub> = 100 mA		95	100	mA
Operation Current						
VBUS Consumption	I <sub>Q_BUS</sub>	Charger, fuel gauge, buck, and buck boost enabled, no charge current		1.5	2	mA
Battery Consumption	I <sub>Q_PRO</sub>	Enable battery protection only, $V_{VBUS} = 0 V$		0.25	1.8	μΑ
	Iq_fg_act	Fuel gauge, active mode, $V_{VBUS} = 0 V$		3.5	5	μΑ
	$I_{Q\_FG\_SLEEP}$	Fuel gauge, sleep mode, $V_{VBUS} = 0 V$		0.2	0.85	μΑ
	$I_{Q_{REG}}$	Enable buck and buck boost, $V_{VBUS} = 0 V$		0.34	1	μΑ
	I <sub>Q_DISALL</sub>	All disabled, $V_{VBUS} = 0 V$		150	450	nA
	$I_{Q_SHIP}$	Shipment mode, T <sub>J</sub> = 25°C		10	50	nA
		Shipment mode, $T_J = -40^{\circ}C$ to $+85^{\circ}C$			310	nA
CHARGING PARAMETERS						
Fast Charge Constant Current						
Mode	Існд	I <sub>CHG</sub> = 100 mA	94	100	106	mA
Accuracy <sup>1</sup>		$I_{CHG} = 10 \text{ mA to } 320 \text{ mA}, T_J = 0^{\circ}\text{C to } 85^{\circ}\text{C}$	-15		+15	%
Charge Current						
Trickle <sup>1</sup>	I <sub>trk_dead</sub>	$I_{TRK\_DEAD} = 5 \text{ mA}, T_J = 0^{\circ}\text{C} \text{ to } 85^{\circ}\text{C}$	4	5	6	mA
Weak	I <sub>CHG_WEAK</sub>			$I_{TRK\_DEAD} + I_{CHG}$		mA
Trickle to Weak Charge Threshold <sup>1</sup>	V <sub>TRK_DEAD</sub>	$V_{\text{TRK}_{\text{DEAD}}} = 2.5 \text{ V}$	2.41	2.5	2.57	v
Hysteresis	$\Delta V_{\text{TRK}\_\text{DEAD}}$			100		mV
Weak to Fast Charge Threshold <sup>1</sup>	VWEAK	$V_{WEAK} = 3.0 V$	2.88	3.0	3.08	v
Hysteresis	$\Delta V_{\text{WEAK}}$			100		mV
Battery Termination Voltage	V <sub>TRM</sub>					
Termination Voltage Accuracy <sup>1</sup>		$V_{TRM} = 4.2$ V on the BSNS pin, $T_J = 25^{\circ}C$	4.18	4.200	4.22	v
		$V_{TRM} = 4.2 \text{ V}$ , on the BSNS pin, $T_J = 0^{\circ}$ C to 85°C	-1		+1	%
Charge Complete Current <sup>1</sup>	I <sub>END</sub>	$I_{END} = 5 \text{ mA}, T_J = 0^{\circ}\text{C to } 85^{\circ}\text{C}$	2	5	8	mA
Recharge Voltage Differential <sup>1</sup>	V <sub>RCH</sub>			120		mV
BATTERY ISOLATION FET	ISOFET					
Resistance Between ISOB and VSYS	R <sub>dson_iso</sub>	$V_{VBUS} = 0 V$ , current of the ISOB pin ( $I_{ISOB}$ ) = 100 mA		145	220	mΩ
LOW DROPOUT (LDO) AND HIGH VOLTAGE BLOCKING FET						
Regulated System Voltage <sup>1</sup>	$V_{\text{SYS}\_\text{REG}}$	$V_{\text{TRM}} = 4.2 \text{ V}, V_{\text{SYSTEM}} = V_{\text{TRM}} + 200 \text{ mV}$		4.4		v
High Voltage Blocking FET On Resistance	R <sub>DSON_HV</sub>	$I_{VBUS} = 100 \text{ mA}$		550	820	mΩ
Input Operating Voltage Range		V <sub>VBUS</sub>	4.1		6.8	v
Good Threshold	V <sub>VBUS_OK</sub>					
Rising	$V_{\text{VBUS}_{OK}_{RISE}}$			3.9	4.0	v
Falling	Vvbus_ok_fall		3.5	3.6		v
Overvoltage Threshold	Vvbus_ov					
Rising	Vvbus_ov_rise			6.8	7.0	v
Falling	VVBUS OV FALL		6.4	6.6		v

# Data Sheet

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Max	Unit
THERMAL PROTECTION						
Thermal Shutdown Temperature <sup>2</sup>	T <sub>SD</sub>	Tjrising		110		°C
		TJ FALLING		100		°C
THERMISTOR CONTROL						
Thermistor Current						
Negative Temperature Coefficient (NTC) Resistor ( $R_{NTC}$ ) = 10 k $\Omega$	I <sub>NTC_10k</sub>		57.5	60	62	μΑ
$R_{NTC} = 47 \ k\Omega$	I <sub>NTC_47k</sub>		11.5	12	12.5	μΑ
$R_{NTC} = 100 \ k\Omega$	INTC_100k		5.65	6	6.35	μA
BATTERY DETECTION						
Sink Current	I <sub>sink</sub>		4.1	6	7	mA
Source Current	ISOURCE		2	2.5	3	mA
Battery Threshold						
Low	VBATL		1.92	2	2.06	V
High	VBATH		3.27	3.4	3.48	V
Timer	t <sub>ваток</sub>			333		ms
Threshold After Charging Completed	$V_{\text{NOBAT}}$			2		V
TIMERS						
Start Charging Delay Timer	tstart			300		ms
Trickle Charge Timer <sup>1</sup>	t <sub>trk</sub>	CHG_TMR_PERIOD = 60 minutes and 600 minutes		60		min
Fast Charge Timer <sup>1</sup>	t <sub>снд</sub>	CHG_TMR_PERIOD = 60 minutes and 600 minutes		600		min
Charge Complete Timer	t <sub>end</sub>	Voltage of the BSNS pin ( $V_{BSNS}$ ) = $V_{TRM}$ , EN_TEND = 1 bit, register set		7.5		min
Deglitch Timer	t <sub>DG</sub>	Applies to V <sub>TRM</sub> , V <sub>RCH</sub> , I <sub>END</sub> , V <sub>WEAK</sub> , V <sub>TRK_DEAD</sub> , and V <sub>VBUS</sub> OK		31		ms
Safety Timer	t <sub>SAFE</sub>		36	40	44	min
Reset Timeout Period	t <sub>RP</sub>			200		ms
MR for Shipment Mode	t <sub>sн</sub>			200		ms
Watchdog Timer <sup>1</sup>	t <sub>wD</sub>			12.5		sec
I <sup>2</sup> C (SCL AND SDA)						
Maximum Voltage on Digital Inputs	V <sub>DIN MAX</sub>				5.5	v
Input Voltage	_					
Low Level	VIL	Applies to SCL, SDA			0.4	v
High Level	VIH	Applies to SCL, SDA	1.2			v
Low Level Output Voltage	Vol	Applies to SDA, SDA current sink (I <sub>SDA_SINK</sub> ) =			0.4	V
		2 mA				
INT, RESET, PGOOD1, AND PGOOD2						
Input and Output Leakage Current	IIO_LEAK	Input and output voltage ( $V_{IO}$ ) = 5 V		10	150	nA
Input and Output Low Voltage	V <sub>IO_LOW</sub>	Input and output current $(I_{IO}) = 1 \text{ mA}$		90	200	mV
ENCHG, EN1, EN2, STP, MR, ENSD			1			1
Input Voltage Threshold						
High	VIH		1.2			v
Low	VIL				0.4	V
Input Leakage Current	I <sub>EN_LEAKAGE</sub>				150	nA

<sup>1</sup> These values are programmable via I<sup>2</sup>C. Values are given with default register values.
 <sup>2</sup> Specification is not production tested but is supported by characterization data at initial product release.

# **BATTERY MONITOR SPECIFICATIONS**

 $T_J = -40^{\circ}$ C to  $+85^{\circ}$ C,  $V_{ISOB} = 3.8$  V,  $C1 = 2.2 \mu$ F,  $C2 = 1 \mu$ F,  $C3 = C4 = 10 \mu$ F, and all registers are at default values, unless otherwise noted.

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Max	Unit
BATTERY VOLTAGE SENSING						
Analog-to-Digital Converter (ADC) Reading Voltage						
Range			0		4.8	V
Resolution		Based on 12-bit ADC		1.17		mV
Accuracy		T」 = 25°C	-12.5		+12.5	mV
			-1		+1	%
Fuel Gauge UVLO Threshold		V <sub>BSNS</sub>				
Rising	$V_{\text{UVLO}_{FG}_{RISE}}$			2.7	2.8	V
Falling	VUVLO_FG_FALL		2.48	2.58		V
BATTERY OVERDISCHARGE MONITORING						
Undervoltage Threshold						
Rising	VBPUV_FALL		-1.5		+1.5	%
Falling Hysteresis	$V_{\text{BPUV}_{\text{FALL}_{\text{HYS}}}}$	$HYS_UV_DISCH = 2\%$		2		%
Undervoltage Deglitch Timer	t <sub>BPUV_DIS</sub>	DGT_UV_DISCH = 30 ms		30		ms
Overdischarge Current						
Threshold	IBPOC_DIS	OC_DISCH = 600 mA	480	600	700	mA
Deglitch Timer	t <sub>BPOC_DIS</sub>	DGT_OC_DISCH = 5 ms		5		ms
Hiccup Off Time	t <sub>DIS_HCP</sub>			200		ms
BATTERY OVERCHARGE MONITORING		$V_{VBUS} = 5 V$				
Overvoltage Threshold						
Rising	VBPOV_RISE		-1.5		+1.5	%
Falling Hysteresis	$V_{\text{BPOV}_{\text{RISE}_{\text{HYS}}}}$	$HYS_OV_CHG = 2\%$		2		%
Overvoltage Deglitch Timer	t <sub>BPOV_CHG</sub>	DGT_OV_CHG = 0.5 sec		0.5		sec
Overcurrent Threshold	IBPOC	OC_CHG = 150 mA	130	150	170	mA
Overcurrent Deglitch Timer	t <sub>BPOC_CHG</sub>	DGT_OC_CHG = 10 ms		10		ms
Hiccup Off Time	t <sub>CHG_HCP</sub>			200		ms

# **BUCK REGULATOR SPECIFICATIONS**

 $T_J = -40^{\circ}$ C to +85°C, voltage of the VIN1 pin (V<sub>VIN1</sub>) = voltage of the VSYS pin (V<sub>VSYS</sub>) = 3.8 V, buck output voltage (V<sub>OUT1</sub>) = 1.2 V, C5 = C6 = 10  $\mu$ F, L1 = 4.7  $\mu$ H (see Figure 60), and all registers are at default values, unless otherwise noted.

Table 3.							
Parameter	Symbol	Test Conditions/Comments	Min	Тур	Мах	Unit	
UVLO THRESHOLD		V <sub>VIN1</sub>					
Rising	V <sub>UVLO1_RISE</sub>			2.3	2.35	V	
Falling	$V_{\text{UVLO1}_{\text{FALL}}}$		2.15	2.2		V	
OSCILLATOR CIRCUIT							
Switching Frequency in Pulse Width Modulation (PWM) Mode	f <sub>sw1</sub>		0.85	1.0	1.15	MHz	
Feedback Threshold of Frequency Fold	Vosc_fold_rise	V <sub>OUT1</sub> = 2.5 V		1.25		٧	
FB1 PIN							
Output Voltage Option Range	Vout1	Factory trim or I <sup>2</sup> C, six bits	0.6		3.75	V	
PWM Mode							
Fixed Voltage Identification (VID) Code Voltage Accuracy	VFB1_PWM_FIX		-2		+2	%	

# **Data Sheet**

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Max	Unit
Hysteresis Mode						
Fixed VID Code Voltage Threshold Accuracy	V <sub>FB1_HYS_FIX</sub>		-2		+2	%
Hysteresis of Voltage Threshold	VFB1_HYS (HYS)			1		%
Feedback Bias Current	I <sub>FB1</sub>	V <sub>OUT1</sub> = 0.6 V		50		nA
SW1 PIN						
Power FET On Resistance						
High-Side	Rds (ON) H	Pin to pin measurement		280	380	mΩ
Low-Side	Rds (ON) L	Pin to pin measurement		260	380	mΩ
Current Limit in PWM Mode	ILIM_PWM	PWM mode	850	1000	1150	mA
Peak Current in Hysteresis Mode	I <sub>LIM_HYS</sub>	Hysteresis mode, BUCK_ILIM = 200 mA	160	200	240	mA
Minimum On Time <sup>1</sup>	t <sub>MIN_ON</sub>			60		ns
SOFT START						
Default Soft Start Time	t <sub>ss1</sub>	BUCK_SS[1:0] = 1 ms		1		ms
OUTPUT DISCHARGE SWITCH ON RESISTANCE	R <sub>DIS1</sub>			255		Ω

<sup>1</sup> Guaranteed by design.

# **BUCK BOOST REGULATOR SPECIFICATIONS**

 $T_J = -40^{\circ}$ C to +85°C, voltage of the VIN2 pin ( $V_{VIN2}$ ) =  $V_{VSYS}$  = 3.8 V, voltage of the VOUT2 pin ( $V_{VOUT2}$ ) = 5 V,  $C_7 = C_8 = 10 \mu$ F, L2 = 4.7  $\mu$ H (see Figure 60), and all registers are at default values, unless otherwise noted.

Table 4.						
Parameter	Symbol	Test Conditions/Comments	Min	Тур	Мах	Unit
UVLO THRESHOLD		V <sub>VIN2</sub>				
Rising	VUVLO2_RISING			2.3	2.36	v
Falling	VUVLO2_FALLING		2.11	2.16		v
OUTPUT VOLTAGE RANGE		Factory trim or I <sup>2</sup> C, six bits	1.8		5.5	V
Output Voltage Accuracy	Vvout2		-2		+2	%
Hysteresis of Voltage Threshold Accuracy	Vvout2_hys			1		%
SW2A AND SW2B PINS						
SWA2 Pin FET Resistance						
High-Side	R <sub>DS(ON)1_2A-H</sub>			354	470	mΩ
Low-Side	RDS(ON)1_2A-L			250	360	mΩ
SW2B Pin FET Resistance						
High-Side	R <sub>DS(ON)1_2B-H</sub>			290	400	mΩ
Low-Side	R <sub>DS(ON)1_2B-L</sub>			230	330	mΩ
Peak Current-Limit Threshold	I <sub>TH(ILIM1_2)</sub>	BUCKBST_ILIM = 200 mA	160	200	240	mA
SOFT START TIME						
Soft Start Time	t <sub>SS2</sub>	BUCKBST_SS[0:1] = 1 ms		1		ms
Programmable Soft Start Range			1		512	ms
OUTPUT DISCHARGE SWITCH ON RESISTANCE	R <sub>DIS2</sub>			255		Ω

# I<sup>2</sup>C-COMPATIBLE INTERFACE TIMING SPECIFICATIONS

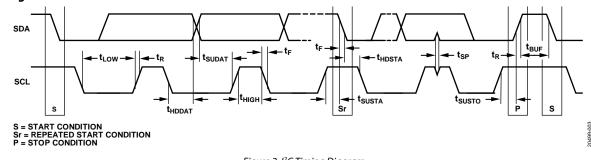
 $T_{\text{A}}$  = 25°C and  $V_{\text{ISOB}}$  = 3.8 V, unless otherwise noted.

#### Table 5.

Parameter	Symbol	Min	Тур	Max	Unit
I <sup>2</sup> C-COMPATIBLE INTERFACE					
Capacitive Load, Each Bus Line	Cs			400	pF
SCL Clock Frequency	<b>f</b> <sub>SCL</sub>			400	kHz
SCL High Time	thigh	0.6			μs
SCL Low Time	t <sub>LOW</sub>	1.3			μs
Data Setup Time	tsudat	100			ns
Data Hold Time <sup>1</sup>	<b>t</b> hddat	0		0.9	μs
Setup Time for Repeated Start	tsusta	0.6			μs
Hold Time for Start and Repeated Start	<b>t</b> hdsta	0.6			μs
Bus Free Time Between a Stop Condition and a Start Condition	t <sub>BUF</sub>	1.3			μs
Setup Time for Stop Condition	t <sub>susto</sub>	0.6			μs
Rise Time of SCL and SDA	t <sub>R</sub>	20		300	ns
Fall Time of SCL and SDA	t <sub>F</sub>	20		300	ns
Pulse Width of Suppressed Spike	t <sub>sP</sub>	0		50	ns

<sup>1</sup> A master device must provide a hold time of at least 300 ns for the SDA signal to bridge the undefined region of the falling edge of SCL. See Figure 2 for more information.

#### **Timing Diagram**



#### Figure 2. I<sup>2</sup>C Timing Diagram

# **RECOMMENDED INPUT AND OUTPUT CAPACITANCE AND INDUCTANCE**

#### Table 6.

Parameter	<b>Test Conditions/Comments</b>	Min	Тур	Мах	Unit
CAPACITANCE	Effective capacitance				
VBUS Capacitance		1.0	2.2		μF
VDD Pin Capacitance		0.47	1.0	10	μF
Total Capacitance					
VSYS Pin		4.7	10		μF
ISOB Pin		4.7	10		μF
VIN1 Pin		2.2	10		μF
VIN2 Pin		2.2	10		μF
VOUT1 Node		1	10		μF
VOUT2 Pin		1	10		μF
INDUCTANCE					
Buck		2.2	4.7	6.8	μH
Buck Boost		2.2	4.7	6.8	μH

# **ABSOLUTE MAXIMUM RATINGS**

#### Table 7.

Parameter	Rating
VBUS to PGND1	–0.5 V to +20 V
PGND1, PGND2 to AGNDx	–0.3 V to +0.3 V
All Other Pins to AGNDx	–0.3 V to +6 V
Continuous Drain Current, Battery Supplementary Mode from ISOB to VSYS, TJ = 85°C	1.1 A
Temperature Range	
Storage	–65°C to +150°C
Operating Junction	-40°C to +85°C
Soldering Conditions	JEDEC J-STD-020

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

# THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

 $\theta_{JA}$  is the natural convection, junction to ambient, thermal resistance measured in a one cubic foot sealed enclosure.  $\theta_{JC}$  is the junction to case thermal resistance.

#### Table 8. Thermal Resistance

Package Type	θ <sub>JA</sub>	θ」	Unit
CB-32-2	50	0.35	°C/W

# MAXIMUM POWER DISSIPATION

The maximum safe power dissipation in the ADP5360 package is limited by the associated rise in T<sub>J</sub> on the die. At approximately 150°C, which is the glass transition temperature, the plastic changes properties. Even temporarily exceeding this temperature limit can change the stresses that the package exerts on the die, permanently shifting the parametric performance of the ADP5360.

# **ESD CAUTION**



**ESD** (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

# **PIN CONFIGURATION AND FUNCTION DESCRIPTIONS**

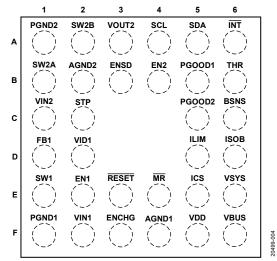


Figure 3. Ball Configuration (Top View)

#### **Table 9. Ball Function Descriptions**

Ball No.	Mnemonic	Description
A1	PGND2	Power Ground for the Buck Boost Regulator.
A2	SW2B	Switching Node for the Buck Boost Regulator.
A3	VOUT2	Buck Boost Regulator Output Pin.
A4	SCL	I <sup>2</sup> C Serial Clock. This pin requires an external pull-up resistor.
A5	SDA	I <sup>2</sup> C Serial Data. This pin requires an external pull-up resistor.
A6	INT	Processor Interrupt (Active Low). This pin requires an external pull-up resistor. If this pin is not used, this pin can be left floating.
B1	SW2A	Switching Node for the Buck Boost Regulator.
B2	AGND2	Analog Ground.
B3	ENSD	Shutdown Mode Select. When this pin is low, the shutdown mode disables. When this pin is high, the shutdown mode enables.
B4	EN2	Enable Pin for Buck Boost Regulator.
B5	PGOOD1	Power-Good Signal Output. This open-drain output is the power-good signal for the selected VBUSOK, BATOK, CHG_CMPLT, VOUT2OK, or VOUT1OK bits (see Table 65).
B6	THR	Battery Pack Thermistor Connection.
C1	VIN2	Input Power for the Buck Regulator.
C2	STP	Stop Switching for the Selected Channel.
C5	PGOOD2	Power-Good Signal Output. This open-drain output is the power-good signal for the selected VBUSOK, BATOK, CHG_CMPLT, VOUT2OK, or VOUT1OK bits (see Table 65).
C6	BSNS	Battery Voltage Sense.
D1	FB1	Feedback Sensing Input for the Buck Regulator.
D2	VID1	Configure Buck Regulator Output Voltage. Connect a resistor from VID1 to AGND1 and AGND2 to program the buck regulator default output voltage. Float the pin to disable the pin select feature and use the register default set.
D5	ILIM	Input Current-Limit Select. Connect a resistor to AGND1 and AGND2 to set the default input current-limit level. Float the pin to disable the pin select feature and use the register default set.
D6	ISOB	Battery Supply-Side Input to Internal Isolation FET.

Ball No.	Mnemonic	Description
E1	SW1	Switching Node for Buck Regulator.
E2	EN1	Hardware Enable for Buck Regulators.
E3	RESET	Reset Output.
E4	MR	Manual Reset Input.
E5	ICS	Set Charge Current. Connect one resistor to ground to set the default charge current. Float the pin to disable the pin select feature and use the register default set.
E6	VSYS	Linear Charger, Supply Side Input to the Internal Isolation FET.
F1	PGND1	Power Ground for the Buck Regulator.
F2	VIN1	Input Power for the Buck Regulator.
F3	ENCHG	Logic Input for the Enable Charger Function.
F4	AGND1	Analog Ground.
F5	VDD	Internal Circuit Power Supply.
F6	VBUS	Power Connection to USB VBUS.

# **TYPICAL PERFORMANCE CHARACTERISTICS**

 $T_A = 25^{\circ}$ C,  $V_{VBUS} = 5.0$  V,  $V_{ISOB} = 3.6$  V,  $C1 = 2.2 \mu$ F,  $C2 = 1 \mu$ F,  $C3 = C4 = 10 \mu$ F,  $C5 = C6 = 10 \mu$ F,  $C7 = C8 = 10 \mu$ F,  $L1 = L2 = 4.7 \mu$ H, and all registers are at default values, unless otherwise noted.

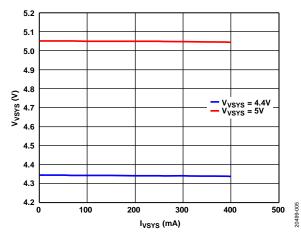


Figure 4. VSYS Load Regulation,  $V_{VSVS} = 4.4$  V and 5 V,  $V_{VBUS} = 5.5$  V,  $I_{VSYS}$  from 1 mA to 400 mA, No Charging

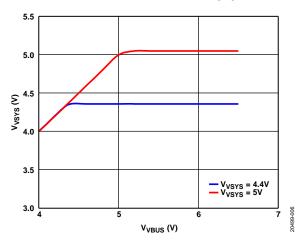


Figure 5. VSYS Line Regulation,  $V_{VSYS} = 4.4 V$  and 5 V, No Charging

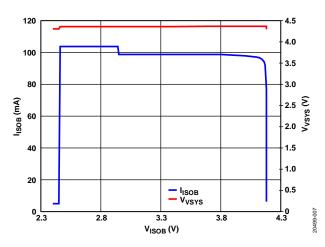
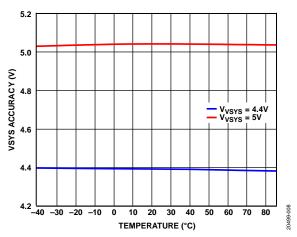
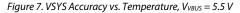


Figure 6. Charge Profile,  $V_{TRM} = 4.2 V$ ,  $I_{CHG} = 100 mA$ 





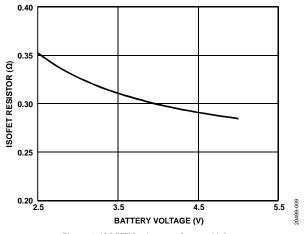


Figure 8. ISOFET Resistor vs. Battery Voltage

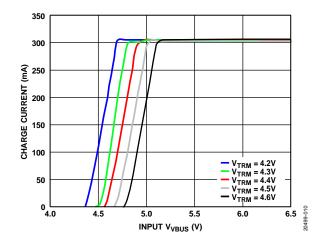
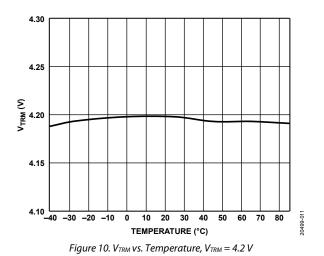
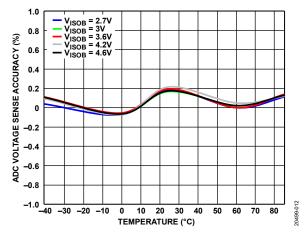


Figure 9. Charge Current vs. Input VVBUS, ICHG = 300 mA

# **Data Sheet**







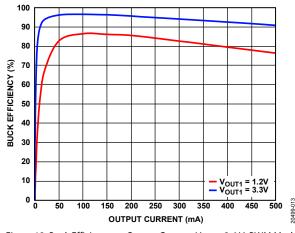
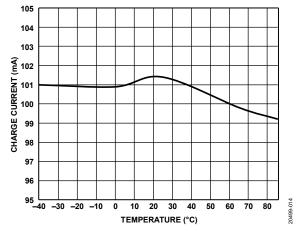
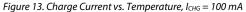
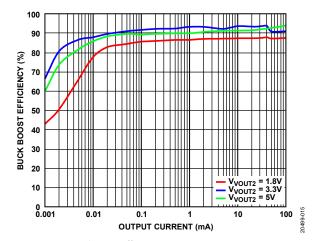
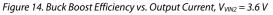


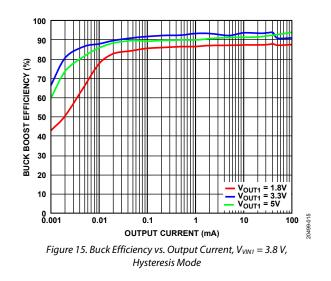
Figure 12. Buck Efficiency vs. Output Current, V<sub>VIN1</sub> = 3.6 V, PWM Mode











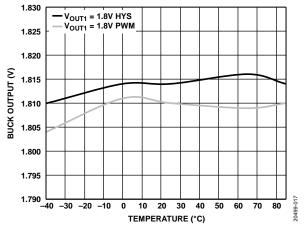


Figure 16. Buck Output vs. Temperature, VFB1\_PWM\_FIX and VFB1\_HYS\_FIX Accuracy

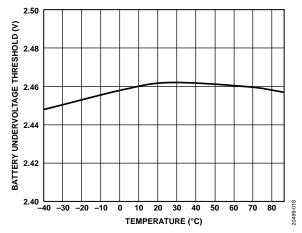


Figure 17. Battery Undervoltage Threshold vs. Temperature, BAT\_UV = 2.5 V

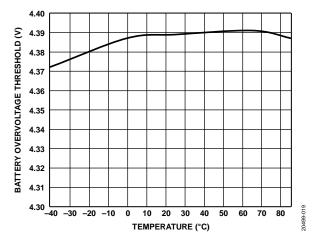


Figure 18. Battery Overvoltage Threshold vs. Temperature, V<sub>BPOV\_RISE</sub> = 4.3 V

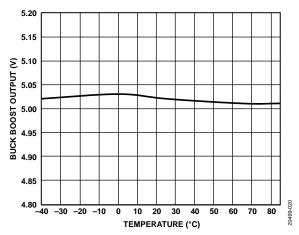


Figure 19. Buck Boost Output vs. Temperature, VOUT2 Accuracy

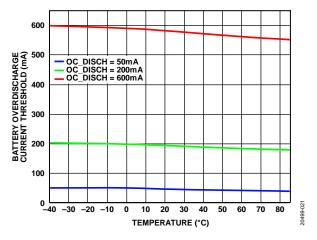


Figure 20. Battery Overdischarge Current Threshold vs. Temperature,  $V_{ISOB} = 3.8 V$ 

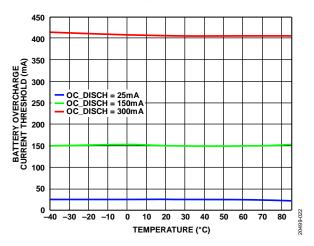


Figure 21. Battery Overcharge Current Threshold vs. Temperature,  $V_{\rm ISOB}=3.8~V$ 

# Data Sheet

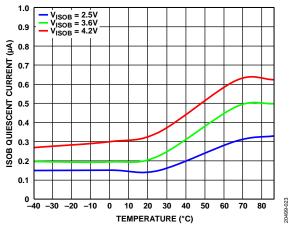


Figure 22. ISOB Quiescent Current vs. Temperature, All Disabled

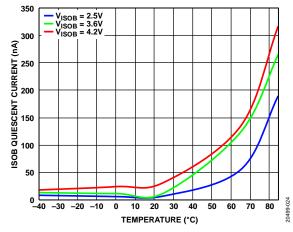


Figure 23. ISOB Quiescent Current vs. Temperature in Shipment Mode

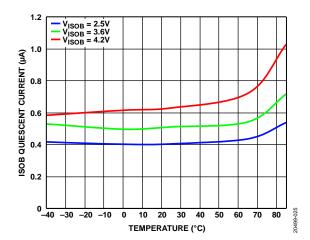


Figure 24. ISOB Quiescent Current vs. Temperature, Fuel Gauge Sleep Mode Enabled, Battery Protection Enabled, Buck Enabled, Buck Boost Enabled

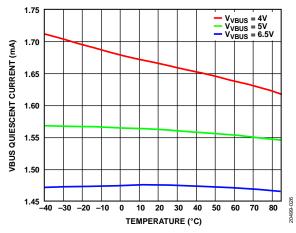
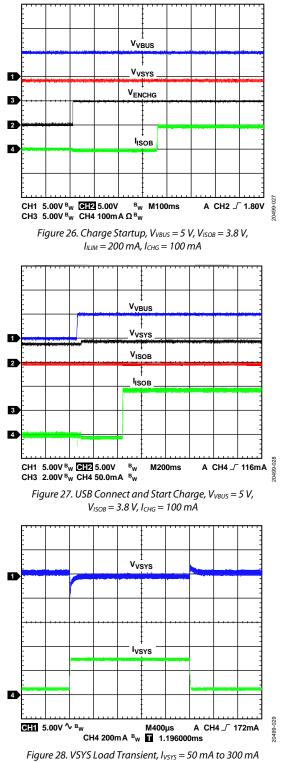


Figure 25. VBUS Quiescent Current vs. Temperature





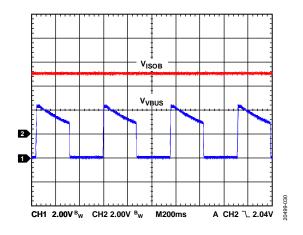


Figure 29. Battery Detection Waveform

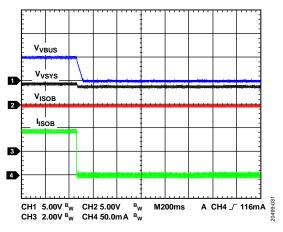


Figure 30. USB Disconnect and End Charge,  $V_{VBUS} = 5 V$ ,  $V_{ISOB} = 3.8 V$ ,  $I_{CHG} = 100 \text{ mA}$ 

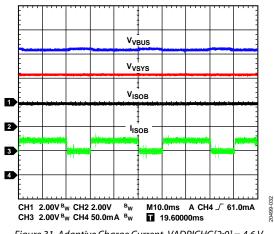
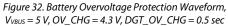


Figure 31. Adaptive Charge Current, VADPICHG[2:0] = 4.6 V,  $V_{VBUS} = 5 V$  with 10  $\Omega$  Impedance,  $I_{CHG} = 100 \text{ mA}$ 

# **Data Sheet**

# CH1 2.00V <sup>B</sup><sub>W</sub> CH2 2.00V <sup>B</sup><sub>W</sub> M200ms A CH1 $\int$ 920mV CH3 1.00V <sup>B</sup><sub>W</sub> CH4 100mA <sup>B</sup><sub>W</sub>



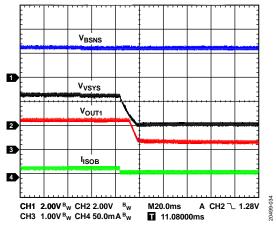


Figure 33. Battery Undervoltage Protection Waveform,  $V_{VBUS} = 0 V, UV_DISCH = 2.5 V, DGT_UV_DISCH = 30 ms$ 

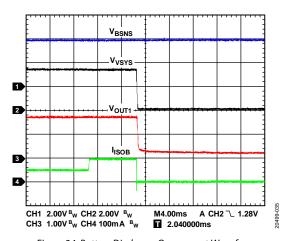


Figure 34. Battery Discharge Overcurrent Waveform,  $V_{VBUS} = 0 V, V_{ISOB} = 3.8 V, OC_DISCH = 100 mA, DGT_OC_DISCH = 10 ms$ 

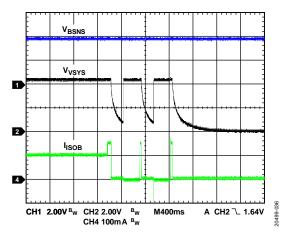


Figure 35. Battery Charge Overcurrent Waveform,  $V_{VBUS} = 5 V$ ,  $V_{ISOB} = 3.8 V$ ,  $OC\_CHG = 150 \text{ mA}$ ,  $DGT\_OC\_CHG = 10 \text{ ms}$ 

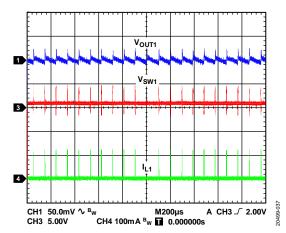
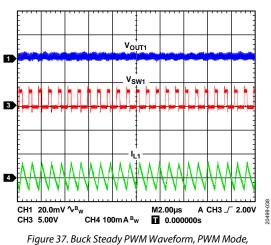
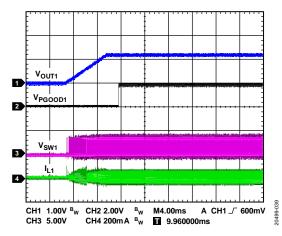
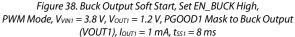


Figure 36. Buck Steady Hysteresis Waveform, Hysteresis Mode, V<sub>VIN2</sub> = 3.8 V, V<sub>OUT1</sub> = 1.2 V, Buck Output Current (I<sub>OUT1</sub>) = 1 mA



 $V_{VIN1} = 3.8 V, V_{OUT1} = 1.2 V, I_{OUT1} = 1 mA$ 





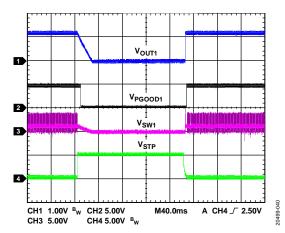


Figure 39. Buck Stop Function Waveform, VVIN1 = 3.8 V, VOUT1 = 1.2 V, Hysteresis Mode, PGOOD1 Mask to VOUT1, STP\_BUCK = 1 Bit

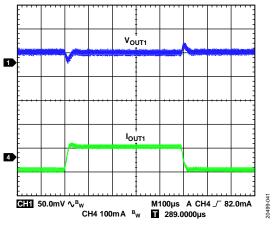


Figure 40. Buck Output Transient Waveform,  $V_{VIN1} = 3.8 V$ ,  $V_{OUT1} = 1.2 V$ ,  $I_{OUT1} = 1 \text{ mA to 100 mA, PWM Mode}$ 

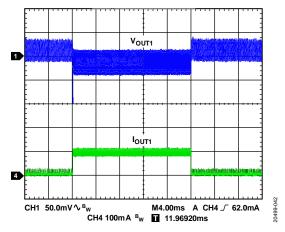


Figure 41. Buck Output Transient Waveform,  $V_{VIN1} = 3.8 V$ ,  $V_{OUT1} = 1.2 V$ ,  $I_{OUT1} = 1 \text{ mA to } 100 \text{ mA}$ , Hysteresis Mode

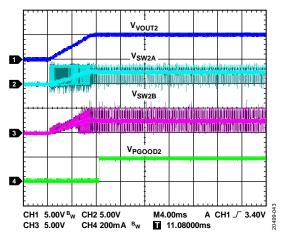
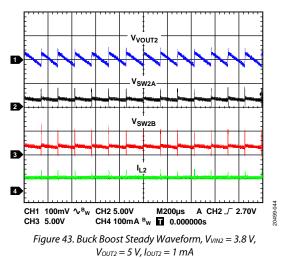


Figure 42. Buck Boost Output Soft Start Waveform,  $V_{VN2} = 3.8 V$ ,  $V_{OUT2} = 5 V$ , BUCKBST\_SS[0:1] = 8 ms, Buck Boost Output Current ( $I_{OUT2}$ ) = 1 mA, PGOOD2 Mask to VOUT2



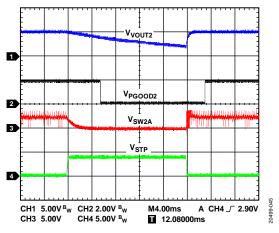
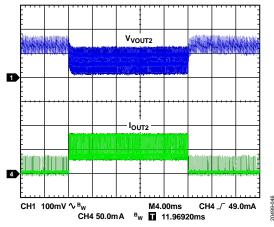
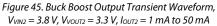
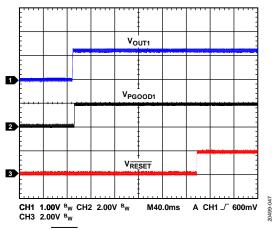
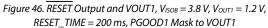


Figure 44. Buck Boost Stop Function Waveform, V<sub>VIN2</sub> = 3.8 V, V<sub>VOUT2</sub> = 5 V, PGOOD2 Mask to VOUT2, STP\_BUCKBST = 1 Bit









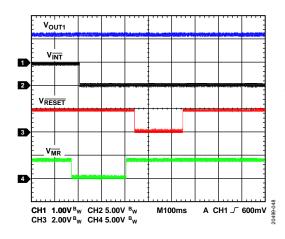


Figure 47. MR Press to Trigger Interrupt and RESET, EN\_WD\_INT = 1 Bit, RESET\_TIME = 200 ms

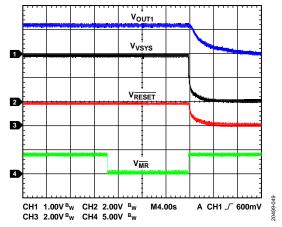


Figure 48. Press  $\overline{MR}$  for Greater than 12 sec to Enter Shipment Mode, EN\_MR\_SD = 1 Bit, ENSD Pin High

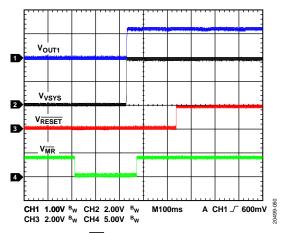


Figure 49. Press MR to Exit Shipment Mode, ENSD Pin High

# THEORY OF OPERATION BATTERY CHARGER

#### **Charger Introduction**

The ADP5360 integrates a fully I<sup>2</sup>C-programmable charger for single-cell Li-Ion/Li-Poly batteries suitable for a wide range of portable applications.

The linear charger architecture enables up to 500 mA of output current on the system power supply and up to 320 mA of charge current into the battery from a dedicated charger.

The charger of the ADP5360 operates from an input voltage of up to 6.8 V but is tolerant of voltages up to 20 V to alleviate the concern of USB bus spiking during disconnection or connection scenarios.

The ADP5360 features an internal FET between the linear charger output and the battery node to permit battery isolation and system power in a dead battery or no battery scenario, allowing instanteneous system function when connected to a USB power supply.

The charger of the ADP5360 enables charging via the mini VBUS pin (F6 pin) from a wall charger, car charger, or USB host port. Based on the type of USB source, which is detected by an external USB detection device, the ADP5360 can apply the proper current limit for optimal charging and USB compliance. The USB charger permits correct operation under all USB compliant sources including wall chargers, host chargers, hub chargers, and standard hosts and hubs.

A processor controls the USB charger using the I<sup>2</sup>C to program the charging current and numerous other parameters, including the following:

- Trickle charge current level and voltage threshold
- Fast charge (constant current) current level
- Fast charge (constant voltage) termination voltage level
- Fast charge safety timer period
- Weak battery threshold detection
- End of charge current level for charge completion
- Recharge voltage threshold
- VBUS input current limit

#### Input Current Limit and USB Compatibility

The VBUS input current limit is programmed via an internal  $I^2C$  ILIM register (R<sub>ILIM</sub>) from 50 mA to 500 mA, ensuring compatibility with different requirements. An external resistor from the ILIM pin to ground can also set the input current limit as the default. Floating the ILIM pin activates the register default value when powering up.

Table 10. VBUS Input Current-Limit Default Set with ILIM Pin				
R <sub>ILIM</sub> Value (kΩ)	ILIM Value (mA)			
100	50			
68	100			
47	150			
36	200			
27	250			
20	300			
15	400			
10	500			

The current-limit defaults to 100 mA to allow compatibility with a USB host or hub that is not configured. This input current limit resets to a default value of 100 mA during every VBUS power-on cycle, thereby protecting the USB port.

When the input current-limit feature is used, it is possible for the available input current to be too low for the charger to meet the programmed charging current ( $I_{CHG}$ ), and the rate of charge reduces. In this case, the VBUS\_ILIM bit flag sets.

When  $V_{\text{VBUS}}$  is between 3.9 V and 6.8 V, the VBUSOK bit is set.

## Trickle Charge Mode

A deeply discharged Li-Ion cell can exhibit a low cell voltage, making it unsafe to charge the cell at high current rates. The ADP5360 charger uses its trickle charge mode to raise the cell voltage to a safe level for fast charging. A cell with a voltage lower than  $V_{TRK\_DEAD}$  charges with  $I_{TRK\_DEAD}$ . During trickle charge mode, the CHARGER\_STATUS[2:0] bits of the CHARGER\_STATUS1 register are set.

During trickle charging, the VSYS node is regulated to  $V_{SYS\_REG}$  by the linear regulator. The battery isolation FET is off, therefore the battery is isolated from the system power supply. Refer to Table 11 for the  $V_{SYS\_REG}$  output voltages.

#### Table 11. V<sub>SYS\_REG</sub> Output Voltages

	V <sub>SYS_REG</sub> (V)			
VTRM Setting	VSYSTEM = VTRM + 200 mV	V <sub>SYSTEM</sub> = 5 V		
$V_{\text{TRM}} \leq 4.26  \text{V}$	4.4	5		
$4.26  V < V_{\text{TRM}} \le 4.36  V$	4.5	5		
$4.36  V < V_{\text{TRM}} \le 4.46  V$	4.6	5		
$4.46  V < V_{\text{TRM}} \le 4.56  V$	4.7	5		
$4.56  V < V_{\text{TRM}} \le 4.66  V$	4.8	5		

When  $V_{VBUS}$  is lower than the set value of  $V_{SYS\_REG}$ ,  $V_{VSYS}$  cannot be regulated, which impacts the charged current (see Figure 9).

# Trickle Charge Mode Timer

The duration of trickle charge mode is monitored to ensure that the battery revives from the deeply discharged state. If trickle charge mode runs for longer than  $t_{TRK}$  without the cell voltage reaching  $V_{TRK\_DEAD}$ , a fault condition is assumed and charging stops. The battery isolation FET turns off, and VSYS is regulated to  $V_{SYS\_REG}$  by the linear regulator. The fault condition asserts on when the CHARGER\_STATUS[2:0] bits are set to 0b110, allowing the user to initiate the fault recovery procedure specified in the Fault Recovery section.

## Weak Charge Mode (Constant Current)

When the battery voltage exceeds  $V_{TRK\_DEAD}$  but is less than  $V_{WEAK}$ , the charger switches to the weak charge mode, and VSYS is regulated to  $V_{SYS\_REG}$  by the battery isolation FET. Note that,  $V_{SYSTEM} = 5$  V is not active on the output of  $V_{SYS\_REG}$  during charge mode.

During weak charge mode, the battery is charged with programmed  $I_{CHG}$  from VSYS through the isolation FET and  $I_{TRK\_DEAD}$ . Due to the VBUS input current limit, the real charge current ( $I_{CHG}$ ) from VSYS may be less than the programmed value. System load can share the current from VSYS. However,  $I_{TRK\_DEAD}$  always charges the battery during weak charge mode.

# Fast Charge Mode (Constant Current)

When the battery voltage exceeds  $V_{WEAK}$ , the charger switches to fast charge mode, charging the battery with I<sub>CHG</sub>. Address 0x04, ICHG[4:0] programs I<sub>CHG</sub> via the I<sup>2</sup>C interface. During fast charge mode (constant current), the CHARGER\_STATUS[2:0] bits are set to 0b010. The default I<sub>CHG</sub> value can be set by the external resistor from the ICS pin (R<sub>ICS</sub>) to ground. Floating the ICS pin activates the register default value when powering up.

8	8
R <sub>ics</sub> Value (kΩ)	I <sub>CHG</sub> Value (mA)
100	10
68	50
47	80
36	100
27	150
20	200
15	250
10	300

During constant current mode, other features can prevent  $I_{CHG}$ from reaching the full programmed value. Input current limiting for USB compatibility can affect the  $I_{CHG}$  value under certain operating conditions. The battery isolation FET regulates  $V_{VSYS}$  to stay at  $V_{SYS\_REG}$ . Note that,  $V_{SYSTEM} = 5$  V is not active on the output of  $V_{SYS\_REG}$  during charge mode. The ADP5360 features a dynamic charge current that is adaptive when  $V_{VBUS}$  drops too much due to possible high internal impedance. The dynamic charge current monitors  $V_{VBUS}$  and reduces the charge current level when  $V_{VBUS}$  falls lower than the threshold, which can be programed by the I<sup>2</sup>C interface. When the charge current adapts due to the  $V_{VBUS}$  level, the ADPICHG status bit is set high. By default, this feature is disabled and can be enabled by the I<sup>2</sup>C setting.

# Fast Charge Mode (Constant Voltage)

As the battery charges, the voltage rises and approaches  $V_{TRM}$ . The ADP5360 charger monitors  $V_{BSNS}$  to determine when charging ends. However, the internal impedance of the battery pack combined with the PCB and other parasitic series resistances creates a voltage drop between the sense point at the BSNS pin and the cell terminal. To compensate for this voltage drop and ensure a fully charged cell, the ADP5360 enters a constant voltage charge mode when  $V_{BSNS}$  reaches the termination voltage. The ADP5360 reduces charge current gradually as the cell continues to charge, maintaining a voltage of  $V_{TRM}$  on the BSNS pin. During constant voltage fast charge mode, the CHARGER\_STATUS[2:0] bits are set to 0b011.

# Fast Charge Mode Timer

The duration of fast charge mode is monitored to ensure that the battery is charging correctly. If the fast charge mode runs for longer than  $t_{CHG}$  without  $V_{BSNS}$  reaching  $V_{TRM}$ , a fault condition is assumed, charging stops, the battery isolation FET turns off, and VSYS regulates to  $V_{SYS\_REG}$  by the linear regulator. A fault condition asserts on when the CHARGER\_STATUS[2:0] bits are set to 0b110, allowing the user to initiate the fault recovery procedure specified in the Fault Recovery section.

If the fast charge mode runs for longer than  $t_{CHG}$  and the BSNS pin reaches  $V_{TRM}$  but the charge current has not yet fallen lower than  $I_{END}$ , charging stops by turning off the battery isolation FET. Note that the linear regulator still works, and VSYS regulates to  $V_{SYS\_REG}$ . No fault condition is asserted in this circumstance, and the ADP5360 attains charge complete status.

# Safety Timer

If the watchdog timer (see the Watchdog Timer section for more information) expires while in charger mode, the ADP5360 charger initiates  $t_{SAFE}$ . Charging continues for a period of  $t_{SAFE}$ , then stops by turning off the battery isolation FET and setting the CHARGER\_STATUS[2:0] bits to 0b110.

# Charge Complete

The ADP5360 charger monitors the charging current while in constant voltage fast charge mode. When EN\_TEND is low, the current falls lower than  $I_{END}$  for  $t_{DG}$ , and the charger is stopped by turning the battery isolation FET off. The system voltage is maintained at  $V_{SYS\_REG}$  by the linear regulator and sets the CHG\_CMPLT flag. When EN\_TEND is set to high, the charging current falls lower than  $I_{END}$  for another  $t_{END}$ , stopping the charger and setting the CHG\_CMPLT flag.

# Recharge

After the detection of charge is complete, and the battery isolation FET turns off, the ADP5360 charger still monitors the BSNS pin. If the BSNS pin voltage falls by  $V_{RCH}$ , the charger reactivates. Under most circumstances, triggering the recharge threshold results in the charger starting in fast charge mode.

# Battery Charging Enable or Disable

To enable the ADP5360 charging function, set the EN\_CHG bit high or pull the ENCHG pin high. The hardware ENCHG pin is logically ORed with the EN\_CHG bit, Address 0x07. If the charger is disabled, the linear regulator remains turned on and regulatesV<sub>VSYS</sub> to V<sub>SYS\_REG</sub>. The battery isolation FET turns off, and the linear regulator provides the power for the system.

# **BATTERY ISOLATION FET**

The ADP5360 charger features an integrated battery isolation FET for power path control and battery protection. The battery isolation FET isolates a deeply discharged Li-Ion cell from the system power supply in both trickle and fast charge modes, therefore allowing the system to be powered at all times. The battery isolation FET maintains  $V_{\mbox{\scriptsize SYS\_REG}}$  on the VSYS pin.

When VBUS is lower than  $V_{\text{VBUS}\_\text{OK}}$ , the battery isolation FET is in full conducting status.

The battery isolation FET supplements the battery to support high current functions on the system power supply when VBUS current is limited.

When the voltage on VSYS drops lower than ISOB, the battery isolation FET enters full conducting mode.

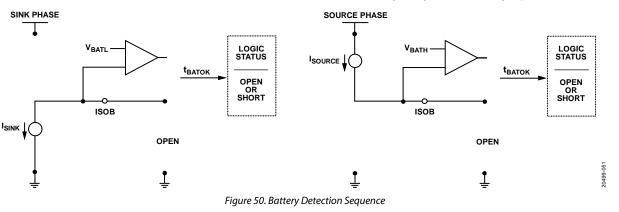
# **BATTERY DETECTION**

## **Battery Level Detection**

The ADP5360 charger features a battery detection mechanism to detect an absent battery. When the charger starts charging, it actively sinks and sources current into ISOB and voltage vs. time is detected. The sink phase detects a charged battery, while source phase detects a discharged battery.

The sink phase sinks current ( $I_{SINK}$ ) from the ISOB pin and the BSNS pin for typically 330 ms (see Figure 50). If the BSNS pin is lower than  $V_{BATL}$  when the 330 ms timer expires, the charger starts the source phase. If the BSNS pin exceeds the  $V_{BATL}$  voltage when the 330 ms timer expires, the charger begins a new charge cycle.

The source phase sources current ( $I_{SOURCE}$ ) to the ISOB pin or the BSNS pin for typically 330 ms. If the BSNS pin exceeds  $V_{BATH}$  before the 330 ms timer expires, it is assumed that no battery is present. If the BSNS pin does not exceed  $V_{BATH}$  when the 330 ms timer expires, it is assumed that a battery is present, and the charger begins a new charge cycle.



# **BATTERY TEMPERATURE**

## **Battery Pack Thermistor Input**

The ADP5360 charger features battery pack temperature sensing that precludes charging when the battery pack temperature is outside of the specified range. The THR pin provides three programmable current sources: 60  $\mu$ A, 12  $\mu$ A, and 6  $\mu$ A. Accordingly, the THR pin supports 10 k $\Omega$ , 47 k $\Omega$ , and 100 k $\Omega$  NTC resistors at 25°C. The THR pin is connected directly to the battery pack thermistor terminal.

When the THR function is enabled, the THR node voltage is sensed by the ADC and can be read in the 12-bit registers, THR\_V\_HIGH and THR\_V\_LOW. Calculate the external thermistor value (R<sub>NTC</sub>) by using the following equation:

 $R_{NTC} = (THR_V/60 \ \mu A)$ 

where:

*THR\_V* is the ADC readback from the THR\_V\_HIGH and THR\_V\_LOW registers.

60  $\mu A$  is selected by the THR pin source current.

To achieve the battery temperature, the  $R_{\mbox{\tiny NTC}}$  value must be known.

When  $V_{VBUS}$  is higher than  $V_{VBUS_OK\_RISE}$ , the THR function is forced to enable for the charger control requirement. The update rate is 1 second. When  $V_{VBUS}$  is lower than  $V_{VBUS\_OK\_RISE}$ , set the

#### Table 13. JEITA Li-Ion Battery Charging Specification Defaults

EN\_THR bit (Address 0x0A) high to enable the THR function. To save quiescent current the THR node voltage update rate slows to 30 seconds.

If the battery pack thermistor is not connected directly to the THR pin, a 100 k $\Omega$  (tolerance ±20%) dummy resistor must be connected between the THR pin and the AGND1 and AGND2 pins. Leaving the THR pin open results in a false detection of a <0°C battery temperature, and charging disables.

The ADP5360 charger monitors the voltage on the THR pin and suspends charging if the voltage is less than 0°C or higher than 60°C. For temperatures greater than 0°C and lower than 60°C, the THR\_STATUS[2:0] bits, Address 0x09, are set accordingly.

#### JEITA Li-lon Battery Temperature Charging Specification

The charge of the ADP5360 is compliant with the JEITA Li-Ion battery charging temperature specifications as shown in Table 13.

The JEITA function can be enabled via the I<sup>2</sup>C interface. When the ADP5360 detects a JEITA cool condition, the charging current reduces, as shown in Table 14.

When the ADP5360 identifies a hot or cold battery condition, the battery isolation FET turns off. The VSYS pin is linear regulated at  $V_{\text{SYS}_{REG}}$  and provides power for the system.

Parameter	Symbol	Conditions	Min	Max	Unit
JEITA Cold Temperature Limits	J <sub>JEITA_COLD</sub>	No battery charging occurs.		0	°C
JEITA Cool Temperature Limits	Ijeita_cool	Battery charging occurs at approximately 50% or 10% of programmed level. See Table 14 for specific charging current reduction levels.	0	10	°C
JEITA Typical Temperature Limits	IJEITA_TYP	Normal battery charging occurs at default and programmed levels.	10	45	°C
JEITA Warm Temperature Limits	Ijeita_warm	Battery termination voltage ( $V_{TRM}$ ) is reduced by 100 mV from programmed value.	45	60	°C
JEITA Hot Temperature Limits	IJEITA_HOT	No battery charging occurs.	60		°C

#### Table 14. JEITA Cool Temperature Limit—Reduced Charge Current Levels

	ICHG JEITA	Value (mA)
ICHG[4:0] Value (mA)	ILIM_JEITA_COOL = 0	ILIM_JEITA_COOL = 1
00000 = 10	10	10
00001 = 20	10	10
00010 = 30	10	10
00011 = 40	20	10
00100 = 50	20	10
00101 = 60	30	10
00110 = 70	30	10
00111 = 80	40	10
01000 = 90	40	10
01001 = 100	50	10
01010 = 110	50	10
01011 = 120	60	10
01100 = 130	60	10

	ICHG JEITA Value (mA)					
ICHG[4:0] Value (mA)	ILIM_JEITA_COOL = 0	ILIM_JEITA_COOL = 1				
01101 = 140	70	10				
01110 = 150	70	20				
01111 = 160	80	20				
10000 = 170	80	20				
10001 = 180	90	20				
10010 = 190	90	20				
10011 = 200	100	20				
10100 = 210	100	20				
10101 = 220	110	20				
10110 = 230	110	20				
10111 = 240	120	20				
11000 = 250	120	30				
11001 = 260	130	30				
11010 = 270	130	30				
11011 = 280	140	30				
11100 = 290	140	30				
11101 = 300	150	30				
11110 = 310	150	30				
11111 = 320	160	30				

## **Battery Charger Operational Flow Chart**

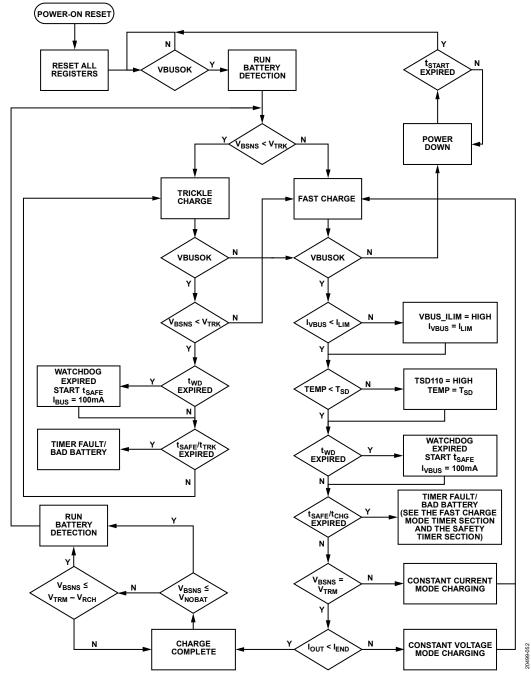


Figure 51. Charger Operational Flowchart

# **BATTERY FUEL GAUGE**

# **General Description**

The ADP5360 Li-Ion battery fuel gauge is optimized through a hybrid algorithm to indicate battery remaining capacity. The battery fuel gauge runs through a coulomb counter and is voltagebased between 0% to 100%. The battery fuel gauge uses a 12-bit ADC to measure the battery node voltage and the battery current. The state of the charge is calculated with an adaptive filter limitation algorithm integrated in the ADP5360. The ten opencircuit battery values and battery capacity are based on the battery characterization written to the V\_SOC\_x registers of the ADP5360 and used for the state of charge calculation. The sense current information, the battery capacity value, the continuous load current, and the large voltage drop all determine the state of the charge change rate. The fuel gauge operates as a coulomb counter with a high accuracy calculation when high continuous

load current is applied. When the battery voltage reaches terminal voltage and charging completes, the battery state of the charge register, BAT\_SOC, indicates 100% for battery capacity.

When the state of charge data is lower than the SOC\_LOW\_TH[1:0] bits configuration, the interrupt asserts, and the SOCLOW\_INT bit is set high for as long as the low state of the charge interrupt feature is allowed.

# **Operation Mode**

The ADP5360 fuel gauge default is shutdown mode to provide extremely low standby current consumption from the battery. After enabling the fuel gauge function, the state of charge initializes and calculates the first data only according to the battery voltage. Two operation modes can be selected: active and sleep. The I<sup>2</sup>C controls fuel gauge operation mode selection.

During active mode, the battery state of charge updates every ten seconds, and the battery voltage and instant current ( $I_{INS}$ ) are sampled every second. The new mapping state of charge compares to the last state of charge value and then updates using the adaptive state of charge limit. According to the sense current and input battery capacity, the ADP5360 calculates the state of charge limit for a state of charge update each cycle.

During sleep mode, the state of charge update cycle is one minute, and the voltage and the current are sampled every 7.5 seconds. During this mode, the 12-bit ADC uses intervals and shutdown mode to save as much quiescent current as possible. Table 15 shows the fuel gauge quiescent current, ADC sample rate, and state of charge update rate. When the sense current is higher than the sleep current threshold setting (Address 0x27, SLP\_CURR[1:0] bits), the ADP5360 fuel gauge exits sleep mode and enters active mode automatically.

# Battery Capacity Adjustment with Aging

The ADP5360 features record total battery charged energy reporting when the device powers up, which allows estimation of battery aging.

The 12 BAT\_SOCACM\_H and BAT\_SOCACM\_L bits accumulate increased state of charge during every charge cycle. For example, the state of charge increases from 20% to 80% during charging, and these bits add 60 points. 100 points indicates one full charge cycle.

When BAT\_SOCACM\_H and BAT\_SOCACM\_L increase and reache 4096 points, and the battery has compiled nearly 41 full charges, then the BAT\_SOCACM\_H and BAT\_SOCACM\_L bits overflow and clear. The interrupt SOCACM\_INT bit in Regiser 0x34 immediately asserts, and the system can adjust the BAT\_CAP register manually or select automatic adjustment by setting the EN\_BATCAP\_AGE bit high. When selecting the battery aging automatic adjustment function, the battery capacity reduction proportion can be programmed by the BATCAP\_AGE bits. When enabling this battery capacity aging automatic adjustment function, the BATCAP\_AGE bits automatic adjustment by rewritten to because this register is automatically adjusted by the ADP5360.

# Battery Capacity Adjustment with Temperature

The Li-Ion battery capacity depends on the ambient operation temperature. The ADP5360 automatically adjusts the battery capacity calculation value based on the temperature variation when setting the EN\_BATCAP\_TEMP bit high. The temperature information comes from the THR node voltage sense. Therefore, the battery THR function must be active, and the EN\_THR bit must be set to high.

The BATCAP\_TEMP[1:0] bits can program the battery capacity calculation value adjustment proportion, and this value decreases as the temperature rises. This battery capacity adjustment is only effective when the THR node voltage senses the corresponding range of the TEMP\_HIGH\_45 to TEMP\_LOW\_0 bits (see Figure 52 and Table 17).

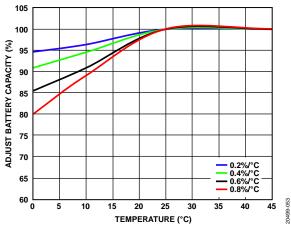


Figure 52. Battery Capacity Adjustment by Temperature in Fuel Gauge

Operation Mode	Typical Quiescent Current (μΑ)	ADC Sample Rate (sec)	State of Charge Update Rate
Sleep	0.2	7.5	1 min
		15	4 min
		30	8 min
		60	16 min
Active	3.5	1	10 sec

#### Table 15. Fuel Gauge Operating Mode

# Flowchart of State of Charge Calculation

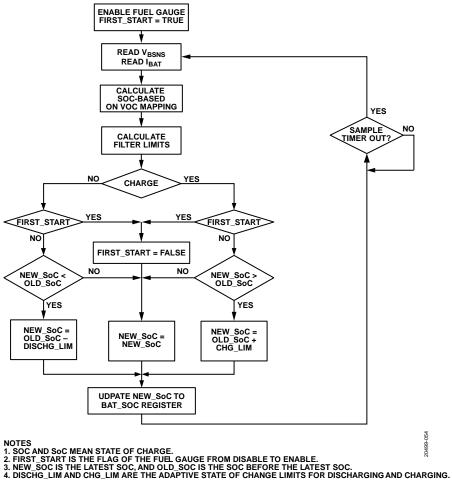


Figure 53. Fuel Gauge Algorithm Flowchart (VOC Mapping Indicates Open-Circuit Battery Voltage Corresponding to 10 V\_SOC\_x Regsiters)

# **BATTERY PROTECTION**

The ADP5360 features a full battery protection feature for Li-Ion and Li-Poly batteries. By default, after  $V_{ISOB}$  rises higher than  $V_{UVLO}$  and exits from shipment mode, battery protection is enabled. The ADP5360 supports the following fault protections:

- Undervoltage protection when the battery overdischarges
- Overdischarge current protection
- Overvoltage protection when the battery overcharges
- Overcharge current protection

When  $V_{BSNS}$  is lower than the battery undervoltage threshold after deglitch time, undervoltage protection triggers, the isolation FET turns off and isolates all system load to the ISOB pin, and the BAT\_UV\_STATUS bit is set high to indicate the battery status and fault register assertion. During undervoltage protection, the charger allows charge to the battery if the EN\_CHGLB bit, Address 0x11, is set to high, and the charger exits undervoltage protection when the battery voltage becomes higher than the undervoltage threshold. The charger does not allow any charge for battery safety consideration if the EN\_CHGLB bit is set low. Use the I<sup>2</sup>C interface to select the undervoltage threshold and response time.

When the battery discharge current going through the isolation FET increases and rises higher than the overcurrent threshold after deglitch time, the overcurrent protection is triggered, and the isolation FET turns off and isolates all system load to the ISOB pin. This protection behavior can be selected to latch-up protection mode or hiccup mode by setting the OC\_DIS\_HICCUP bit, Address 0x11. In latch-up protection mode, the isolation FET turns off and shuts down the VSYS output after retrying three times. When the fault is removed, clearing the fault register or a VBUS power reset can recover normal operation. In hiccup protection mode, the isolation FET attempts to turn on after the typical 200 ms shutdown time until the system load fault is removed.

When triggering battery overvoltage protection, the LDO FET turns off, charging stops, and the LDO FET stays in suspend status. Duirng this protection, the isolation FET is selectable and can be turned off or kept turned.

When triggering the battery overcharge current, the LDO FET turns off, charging stops, and the LDO FET stays in suspend status. The isolation FET also turns off and shuts down the VSYS output. If selecting the latch-up overcharge protection mode, the charger remains in suspend status, and the battery does not allow charging after three retries. If selecting hiccup protection mode, the charger always attempts to restart the charge until the charger fault is removed. Clearing the fault register or VBUS power reset can recover normal operation after the fault is removed.

All battery protection function selection must be done when the ADP5360 powers up. Do not change the battery protection function during battery fault.

# **BUCK REGULATOR OPERATION**

#### **Operation Mode**

The ADP5360 has two operation modes, PWM and hysteresis that are controlled by the  $I^2C$  interface.

# PWM Mode

In PWM mode, the buck regulator operates at a fixed 1 MHz frequency that is set by an internal oscillator. At the start of each oscillator cycle, the high-side MOSFET switch turns on and sends a positive voltage across the inductor. The inductor current increases until the current sense signal exceeds the peak inductor current threshold, which turns off the high-side MOSFET switch. This threshold is set by the error amplifier output. During the high-side MOSFET off time, the inductor current decreases through the low-side MOSFET until the next oscillator clock pulse starts a new cycle.

In PWM mode, the regulator can supply up to 500 mA of average output current. The regulator can provide lower voltage ripple in PWM mode, which is useful for noise sensitive applications.

## Hysteresis Mode

In hysteresis mode, the buck regulator in the ADP5360 charges the output voltage to a higher value than the nominal output voltage with PWM pulses. The buck regulator charges the output voltage by regulating the constant peak inductor current that is programed by the I<sup>2</sup>C interface. When the output sense signal exceeds the hysteresis upper threshold, the regulator enters standby mode. In standby mode, the high-side and low-side MOSFETs and the control circuitry are disabled to allow a low quiescent current as well as a high efficiency performance.

During standby mode, the output capacitor supplies energy into the load, and the output voltage decreases until the voltage falls lower than the hysteresis comparator lower threshold. The buck regulator wakes up and generates the PWM pulses to charge the output again.

Because the output voltage occasionally enters standby mode and then recovers, the output voltage ripple in hysteresis mode is larger than the ripple in PWM mode. The varying switching frequency creates more noise in the system. Therefore, it is recommended to use PWM mode during charging status.

Use the following equation in hysteresis mode to calculate the regulator output current:

 $I_{LOAD1_HYS} = I_{PEAK1_HYS}/2$ 

#### where:

 $I_{LOAD1\_HYS}$  is the regulator output current.  $I_{PEAK1\_HYS}$  is the inductor peak current.

The maximum regulator output current is 100 mA when the limitation of the inductor peak current, BUCK\_ILIM, is set to 200 mA.

# Program Output Voltages

Adjustable output voltage settings are available on the ADP5360 by connecting a resistor through the VID1 pin to the AGND1 and AGND2 pins. The VID detection circuitry works in the start-up period, and the voltage ID code is sampled and held into the internal register and does not change until the next power recycle.

Table 16 lists the output voltage options for the VID1 pin configurations. Additional output voltage options from 0.6 V to 3.75 V with a 50 mV step are available on the ADP5360, and to program these options set the VOUT\_BUCKBST[5:0] bits, Address 0x2C via the I<sup>2</sup>C interface. The ADP5360 also has a fixed output voltage that is programmed via the factory fuse. In this case, connect the VID1 pin to the VIN1 pin.

#### Table 16. VOUT1 Default Set Using the VID1 Pin

VID1 Resistor, $R_{VID1}$ Value (k $\Omega$ )	Vouti Value (V)
100	3.3
68	3.0
47	2.8
36	2.5
27	1.8
20	1.5
15	1.2
10	1.0

For the output voltage settings, the feedback resistor divider is built into the ADP5360, and the feedback pin (FB1) must be tied directly to the output. An ultra low power voltage reference and an integrated high impedance feedback divider network contribute to the low quiescent current. Floating the VID1 pin activates the register default value when powering up.

#### Enable and Disable

The ADP5360 includes a hardware enable pin (EN1). A logic high on the EN1 pin starts the buck regulator. Due to the low quiescent current design, it is typical for the regulator to start switching after a delay of a few milliseconds from when the EN1 pin is pulled high. Do not pull the EN1 pin high to the ISOB pin because that can cause unexpected leakage current. It is recommended to pull the EN1 pin high to the VSYS pin with a resistor.

The EN\_BUCK bit, Address 0x29, can control the buck enable and disable, which is logically ANDed with the EN1 pin. For example, set the EN\_BUCK bit high, and use the EN1 pin control buck to enable or to disable. Alternatively, pull the EN1 pin high and set the EN\_BUCK bit via the I<sup>2</sup>C interface.

# **PGOOD** Indication

The VOUT1OK bit, Address 0x2F, indicates whether the buck regulator is working appropriately. A logic high indicates that the output voltage of the buck regulator is higher than 90% (typical rising threshold) of the nominal output. When the regulated output voltage falls lower than 87% (typical falling threshold) of the nominal output, the VOUT1OK bit goes low.

The status indication of the VOUT1OK bit can be masked to the hardware pin output of the PGOOD1 pin or PGOOD2 pin by setting Register PGOODx\_MASK with the I<sup>2</sup>C interface.

## Soft Start

The ADP5360 buck regulator has an internal soft start function that ramps up the output voltage in a controlled manner during startup, thereby limiting the inrush current. This feature prevents possible input voltage drops when a battery or a high impedance power source is connected to the input of the device. The default typical soft start time is 1 ms for the regulator. Other soft start times (8 ms, 64 ms, and 512 ms) can be programmed for the ADP5360 by the I<sup>2</sup>C interface.

## 100% Duty Cycle Operation

When the input voltage approaches the output voltage, the ADP5360 stops switching and enters 100% duty cycle operation. The buck connects the output via the inductor and the internal high-side power switch to the input. When the input voltage is charged again, and the required duty cycle falls to 95% typical, and the buck immediately restarts switching and regulation without allowing overshoot on the output voltage.

# Active Discharge

The ADP5360 integrates an optional discharge switch from the switching node to ground. This switch turns on when the associated regulator is disabled to help discharge the output capacitor quickly. The typical value of the discharge switch is 255  $\Omega$  for the regulator.

The active discharge feature can be enabled by setting the DISCHG\_BUCK bit, Address 0x29, high for the buck regulator.

# **Current-Limit Protection**

The buck regulator in the ADP5360 has protection circuitry that limits the direction and the amount of current to a certain level that flows through the high-side MOSFET and the low-side MOSFET in cycle by cycle mode. The positive current limit on the high-side MOSFET limits the amount of current that can flow from the input to the output. The negative current limit on the low-side MOSFET prevents the inductor current from reversing direction and flowing out of the load.

## **Short-Circuit Protection**

The buck regulator in the ADP5360 includes frequency foldback to prevent current runaway on a hard short in PWM mode. When the output voltage at the feedback pin (FB1) falls lower than 50% of VOUT1 typical, indicating the possibility of a hard short at the output, the switching frequency is reduced to half of the internal oscillator frequency. The reduction in the switching frequency allows more time for the inductor to discharge, preventing a runaway of output current.

## Stop Switching

The ADP5360 includes one STP pin that can be configured as a stop pin to allow the user to temporarily stop the buck regulator switching.

When applying a logic high level to the STP pin, the corresponding regulator is forced to stop switching immediately. When applying a logic low level to the STP pin, the regulator resumes switching. Note that tens of ns delay time exists from when the STP signal goes high to when switching fully stops.

The stop signal control is valid only when the regulator is enabled. Otherwise, the stop signal is ignored.

Using the stop signal for hysteresis mode can generate a powergood failure due to the slow transient response.

Set the STP\_BUCK bit, Register 0x29, low to disable the buck regulator stop switching feature.

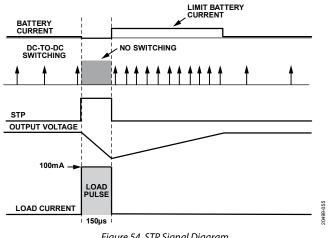


Figure 54. STP Signal Diagram

# **BUCK BOOST REGULATOR OPERATION**

#### **Operation Mode**

The buck boost regulator in the ADP5360 is synchronous with the current mode, switching regulators designed to maintain a fixed output voltage from an input supply (VIN2) that can be greater than, equal to, or less than VOUT2.

The buck boost regulator works in hysteresis mode and regulates the output voltage to a slightly higher value than the target output voltage with switching pulses. When the output voltage increases until the output sense signal exceeds the hysteresis upper threshold, the regulator enters sleep mode. In sleep mode, the high-side and low-side MOSFET and a majority of the control circuitry are disabled to allow a low quiescent current as well as high efficiency performance. During sleep mode, the output capacitor supplies the energy into the load, the output voltage decreases until the voltage falls lower than the hysteresis comparator lower threshold, and the regulator wakes up and generates the switching pulses to charge the output again.

## **Program Output Voltages**

The ADP5360 buck boost regulator provides output voltage options from 1.8 V to 2.9 V with a 100 mV step, and 2.95 V to 5.5 V with 50 mV step, which can be programmed by the VOUT\_BUCKBST[5:0] bits, Address 0x2C, and set via the I<sup>2</sup>C interface (see Table 62). The buck boost regulator also provides a fixed output voltage programmed via the factory fuse.

For the output voltage settings, the feedback resistor divider is built in the ADP5360. An ultra low power voltage reference and an integrated high impedance (50 M $\Omega$  typical) feedback divider network contribute to the low quiescent current.

#### Enable and Disable

The ADP5360 includes a hardware enable pin (EN2). A logic high in the EN2 pin starts the buck boost regulator. Because of the low quiescent current design, it is typical for the regulator to start switching after a delay of a few milliseconds from when the EN2 pin pulls high. To avoid unexpected leakage current, do not pull the EN pin high to the ISOB pin. However, do pull the EN2 pin high to the VSYS pin with the resistor.

The I<sup>2</sup>C register bit, EN\_BUCKBST, Address 0x2B, can also control the buck boost enable and disable, which are logically ORed with the EN2 pin. For example, set the EN\_BUCKBST bit to low, then use the hardware EN2 pin to control the buck boost enable and disable, or pull the EN2 pin low, and then set the EN\_BUCKBST bit using the I<sup>2</sup>C inteface.

# **PGOOD** Indication

The VOUT2OK bit, Address 0x2F, indicates whether the buck boost regulator is working properly. A logic high indicates that the output voltage of the buck boost regulator is higher than 90% (typical rising threshold) of the nominal output. When the regulated output voltage falls lower than 87% (typical falling threshold) of the nominal output, the VOUT2OK bit goes low.

The VOUT2OK bit status indication can be masked to the PGOOD1 pin or PGOOD2 pin by setting the PGOODx\_MASK register with the  $I^2C$  interface.

## Soft Start

The ADP5360 buck boost regulator has an internal soft start function that ramps up the output voltage in a controlled manner upon startup, thereby limiting the inrush current. This feature prevents possible input voltage drops when a battery or a high impedance power source is connected to the input of the device. The default typical soft start time is 1 ms for the regulator. Other soft start times (8 ms, 64 ms, and 512 ms) can be programmed for the ADP5360 by the I<sup>2</sup>C interface.

#### Active Discharge

The ADP5360 integrates an optional discharge switch from the output node to ground. This switch turns on when the associated regulator is disabled to help discharge the output capacitor quickly. The typical value of the discharge switch is 255  $\Omega$  for the regulator.

The active discharge feature can be enabled by setting the DISCHG\_BUCKBST bit, Address 0x2B, high for the buck boost regulator.

#### **Current-Limit Protection**

The buck boost regulator in the ADP5360 includes peak currentlimit protection circuitry to limit the amount of positive current flowing through the high-side MOSFET switch. The peak current limit on the power switch limits the amount of current that can flow from the input to the output. The programmable currentlimit threshold feature allows for the use of small size inductors for low current applications.

Use the BUCKBST\_ILIM[2:0] bits, Address 0x2B, via the I<sup>2</sup>C interface to program the peak current-limit threshold on the buck boost regulator. Three bit-programmable options provide 100 mA to 800 mA of peak current limit with a 100 mA step peak current threshold range. Use the following equation to find the regulator output current:

$$I_{LOAD2} = V_{IN2} \times I_{PEAK2}/2(V_{IN2} + V_{OUT2})$$

#### where:

 $I_{LOAD2}$  is the regulator output current.  $V_{IN2}$  is the regulator input voltage.  $I_{PEAK2}$  is the inductor peak current.  $V_{OUT2}$  is the output voltage. The peak current limit is different than the average current limit on the battery input side. The average battery current is a factor in different elements including, but not limited to, the VIN2/VOUT2 relationship, the inductance, the switching frequency, and the peak current-limit threshold. The average battery current limit on each buck or buck boost regulator can be roughly calculated and predicted by these elements. However, the average current-limit accuracy is difficult to guarantee due to variations in inductance and switching frequency. Therefore, a careful calculation must be obtained if the input source is coming from a weak battery, which typically has high output impedance.

#### Stop Switching

The stop feature also can configure the buck boost regulator with the STP pin input, which allows the user to temporarily stop buck boost regulator switching.

When applyin a logic high level to the STP pin, the corresponding regulator is forced to stop switching immediately. When applying a logic low level to the STP pin, the regulator resumes switching. Note that tens of ns delay time exists from when the STP signal goes high to when switching fully stops.

The stop signal control is valid only when the regulator is enabled. Otherwise, the stop signal is ignored.

Set the STP\_BUCKBST bit, Address 0x2B, low to disable the buck boost regulator stop switching feature.

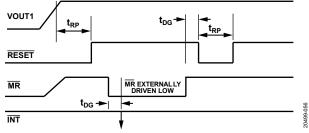
# SUPERVISORY

## Reset Output

The ADP5360 provides microprocessor supply voltage supervision by controlling the reset input of the microprocessor. When the monitored voltage falls lower than the associated threshold, the RESET pin asserts correspondingly. Asserting the RESET pin quickly ensures that the entire system is reset immediately before any part of the system voltage falls lower than the recommended operating voltage. The default monitor voltage is the buck output voltage (VOUT1) and can be selected as VOUT2 by the I<sup>2</sup>C interface. The RESET pin monitors both VOUT1 of the buck and VOUT2 of the buck boost when setting the VOUT1\_RST bit and VOUT2\_RST bit of Address 0x2D both high.

# Manual Reset Input

The ADP5360 features a manual reset input. When driving the  $\overline{MR}$  pin low from high with the deglitch time (t<sub>DG</sub>), the INT pin asserts an interrupt when the EN\_MR\_INT bit, Address 0x33, is set to high. When the  $\overline{MR}$  pin transitions from low to high, the RESET pin output asserts and remains asserted for the duration of the reset timeout period (t<sub>RP</sub>) before deasserting. Connect an external pull-up resistor from the  $\overline{MR}$  input to the VDD pin for a logic high output. To generate a reset, connect an external pushbutton switch between the  $\overline{MR}$  pin and ground. Noise immunity is provided on the  $\overline{MR}$  input, and fast transients going in a negative direction are ignored. A 0.1 µF capacitor between the  $\overline{MR}$  pin and ground provides additional noise immunity if required.





When the EN\_MR\_SD bit, Address 0x2D is set to enable shipment mode, pulling down the MR pin for more than a 12 second time out, and then releasing the MR pin, shuts down all function blocks, and the ADP5360 then enters shipment mode. To exit shipment mode, pull the MR pin low for t<sub>SH</sub>, and the ADP5360 restarts with the default factory setting registers.

# Watchdog Timer

The ADP5360 features a watchdog timer that monitors microprocessor activity. A timer circuit is cleared with every write to the RESET\_WD bit, Address 0x2D. If the timer counts through the preset watchdog timeout period ( $t_{WD}$ ), a RESET output asserts. The microprocessor must toggle the RESET\_WD bit to avoid being reset.

When  $\overrightarrow{\text{RESET}}$  is asserted, the watchdog timer clears and does not count again until the  $\overrightarrow{\text{RESET}}$  output deasserts. To disable the watchdog timer, set the EN\_WD bit, Address 0x2D via the I<sup>2</sup>C interface. Note that the watchdog timer is ignored when RESET is not activated. If the watchdog timer expires without being reset while in charger mode, the ADP5360 charger assumes there is a software problem and triggers  $t_{SAFE}$ . For more information, see the Safety Timer section.

# SHIPMENT MODE

The ADP5360 provides optional shipment mode as a default status after ISOB powers up. During shipment mode, most function blocks shut down, including the ISOFET and VSYS output voltages that realize an ultralow shutdown current. In addition, during shipment mode, the PGOOD1, PGOOD2, and RESET pins have a high output by default.

Enable shipment mode at initial power up of the ADP5360 by pulling up the ENSD pin. To disable shipment mode, pull down the ENSD pin.

In the case where the VBUS voltage goes higher than the UVLO or the  $\overline{\text{MR}}$  pin for t<sub>SH</sub> is pulled down, the ADP5360 exits shipment mode. To re-enter shipment mode, set the EN\_SHIPMODE bit, Address 0x36, to high or pull down the  $\overline{\text{MR}}$  pin for 12 seconds.

Note that the EN\_MR\_SD bit, Address 0x2D must be set to enable the  $\overline{MR}$  shipment function.

# FAULT RECOVERY

Before performing fault recovery, ensure that the cause of the fault is rectified.

To recover from a fault status, power off the VBUS pin or write a high to the corresponding bits of the Fault register.

# THERMAL MANAGEMENT

#### **Thermal Shutdown**

The ADP5360 features a shutdown threshold detector. If the die temperature exceeds  $T_{SD}$ , all functions are disabled, and the TSD110 bit, Address 0x2E, is set. The ADP5360 charger can be re-enabled when the die temperature drops lower than the  $T_{SD}$  falling limit, and the TSD110 bit is reset. To reset the TSD110 bit, write to the I<sup>2</sup>C fault register, THERMISTOR\_10C Threshold, Address 0x0D, or cycle the power.

# **I<sup>2</sup>C INTERFACE**

The ADP5360 includes an I<sup>2</sup>C-compatible serial interface to control the battery charging, fuel gauge, buck, and buck boost, and to read back the system status.

# I<sup>2</sup>C ADDRESSES

The I<sup>2</sup>C chip default address is 0x46. Different I<sup>2</sup>C addresses can be factory programmable. Having different I<sup>2</sup>C address options helps to avoid I<sup>2</sup>C address conflicts with other I<sup>2</sup>C slave chipsets in the system. For different I<sup>2</sup>C chip address requirements, contact the local Analog Devices sales or distribution representative.

# **SDA AND SCL PINS**

The ADP5360 has two dedicated I<sup>2</sup>C interface pins, SDA and SCL. SDA is an open-drain line for receiving and transmitting data. SCL is an input line for receiving the clock signal. Pull up these pins to connect external input and output supplies using external resistors.

Serial data is transferred on the rising edge of SCL. The read data is generated at the SDA pin in read mode.

The subaddress content selects which of the ADP5360 registers is written to first. The ADP5360 sends an acknowledgement to the master after the 8-bit data byte is written (see Figure 56 for an example of the I<sup>2</sup>C write sequence to a single register). The ADP5360 increments the subaddress automatically and starts receiving a data byte at the next register until the master sends an I<sup>2</sup>C stop as shown in Figure 56.

# INTERRUPTS

The ADP5360 provides an interrupt output  $(\overline{\text{INT}} \text{ pin})$  for an interrupt case. During normal operation, the  $\overline{\text{INT}}$  pin is pulled high using an external pull-up resistor. When an interrupt case occurs, the ADP5360 pulls the  $\overline{\text{INT}}$  pin low to alert the I<sup>2</sup>C host that an interrupt case has occurred.

Many different interrupt sources can trigger the INT pin. By default, no interrupt sources are configured. To select one or more interrupt sources to trigger the INT pin, set the corresponding bits to 1 in the INTERRUPT\_ENABLE1 and INTERRUPT\_ENABLE2 registers.

When the  $\overline{\text{INT}}$  pin is triggered, the corresponding bits in the INTERRUPT\_FLAG1 and INTERRUPT\_FLAG2 registers are set to 1. The interrupt case that triggers the  $\overline{\text{INT}}$  pin is read from the INTERRUPT\_FLAG1 and INTERRUPT\_FLAG2 registers.

To clear an interrupt, write a 1 to the corresponding bit in the INTERRUPT\_FLAG1 and INTERRUPT\_FLAG2 registers. Otherwise, the ADP5360 power recycles. Reading the interrupt or writing a 0 to the bit does not clear the interrupt.

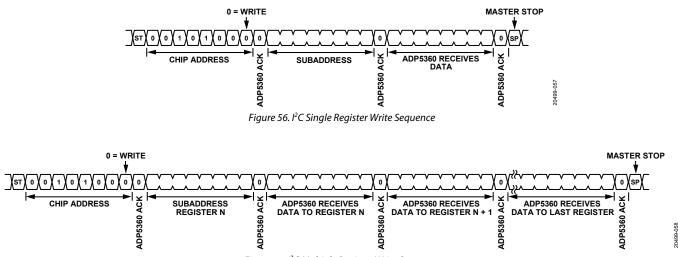
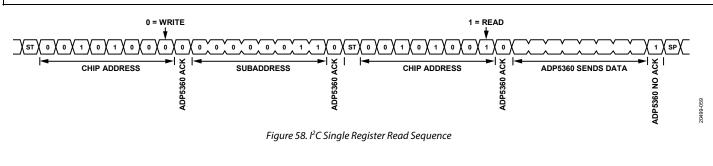
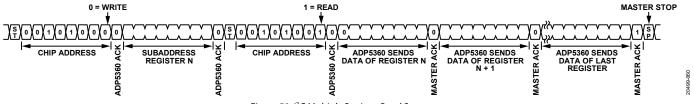
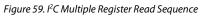


Figure 57. I<sup>2</sup>C Multiple Register Write Sequence







# **CONTROL REGISTER MAP**

Table 17. Register Map

Address (Hex)	Register Name	Bits	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	
0x00	Manufacture and Model ID	[7:0]	MANUF[3:0] MODEL[3:0]					1			
0x01	Silicon Revision	[7:0]	Reserved R				RE	EV[3:0]			
0x02	CHARGER_ VBUS_ILIM	[7:0]		VADPICHG[2:0	0]	Reserved	VSYSTEM		ILIM[2:0]	ILIM[2:0]	
0x03	CHARGER_ TERMINATION_ SETTING	[7:0]		VTRM[5:0]					ITRK_D	0EAD[1:0]	
0x04	CHARGER_ CURRENT_ SETTING	[7:0]		IEND[2:0]				ICHG[4:0]			
0x05	CHARGER_ VOLTAGE_ THRESHOLD	[7:0]	DIS_RCH	VRC	H[1:0]	VTRK_DI	EAD[1:0]		VWEAK[2:0	]	
0x06	CHARGER_ TIMER_ SETTING	[7:0]		Re	served		EN_TEND	EN_CHG_ TIMER	CHG_TMR	_PERIOD[1:0]	
0x07	CHARGER_ FUNCTION_ SETTING	[7:0]	EN_JEITA	ILIM_ JEITA_ COOL	Reserved	OFF_ISOFET	EN_LDO	EN_EOC	EN_ ADPICHG	EN_CHG	
0x08	CHARGER_ STATUS1	[7:0]	VBUS_OV	ADPICHG	VBUS_ILIM	Rese	rved	CHARGER_STATUS[2:0]			
0x09	CHARGER_ STATUS2	[7:0]	Т	THR_STATUS[2:0] BAT_OV_ BAT_UV_ BAT_US				_CHG_STATUS[2:0]			
0x0A	BATTERY_ THERMISTOR_ CONTROL	[7:0]	ITH	ITHR[1:0]			Reserved E			EN_THR	
0x0B	THERMISTOR_ 60C Threshold	[7:0]				TEMP_HIGH	I_60[7:0]				
0x0C	THERMISTOR_ 45C Threshold	[7:0]				TEMP_HIGH	l_45[7:0]				
0x0D	THERMISTOR_ 10C Threshold	[7:0]				TEMP_LOW	/_10[7:0]				
0x0E	THERMISTOR_ 0C Threshold	[7:0]				TEMP_LOV	V_0[7:0]				
0x0F	THR_VOLTAGE Low	[7:0]				THR_V_LC	)W[7:0]				
0x10	THR_VOLTAGE High	[7:0]		Re	served			THR_V_I	HIGH[11:8]		
0x11	Battery Protection Control	[7:0]	Reserved		ISOFET_ OVCHG	OC_DIS_ HICCUP	OC_CHG_ HICCUP	EN_ CHGLB	EN_ BATPRO		
0x12	Battery Protection Undervoltage Setting	[7:0]		UV_DISCH[3:0] HYS_UV_[			HYS_UV_DISCH[1:0] DGT_UV_D		_DISCH[1:0]		
0x13	Battery Protection Overcharge Setting	[7:0]	OC_DISCH[2:0]			Reserved	DG	T_OC_DISCH	[2:0]	Reserved	

Address (Hex)	Register Name	Bits	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
0x14	Battery Protection Overvoltage Setting	[7:0]	OV_CHG[4:0]				HYS_OV_CHG[1:0] DGT_OV_ CHG			
0x15	Battery Protection Charge Overcharge Setting	[7:0]		OC_CHG[2:0]	]	DGT_OC_CHG[1:0]		Reserved		
0x16	V_SOC_0	[7:0]	V_SOC_0[7:0]							
0x17	V_SOC_5	[7:0]	V_SOC_5[7:0]							
0x18	V_SOC_11	[7:0]	V_SOC_11[7:0]							
0x19	V_SOC_19	[7:0]	V_SOC_19[7:0]							
0x1A	V_SOC_28	[7:0]	V_SOC_28[7:0]							
0x1B	V_SOC_41	[7:0]	V_SOC_41[7:0]							
0x1C	V_SOC_55	[7:0]	V_SOC_55[7:0]							
0x1D	V_SOC_69	[7:0]	V_SOC_69[7:0]							
0x1E	V_SOC_84	[7:0]	V_SOC_84[7:0]							
0x1F	V_SOC_100	[7:0]	V_SOC_100[7:0]							
0x20	BAT_CAP	[7:0]	BAT_CAP[7:0]							
0x21	BAT_SOC	[7:0]	Reserved BAT_SOC[6:0]							
0x22	BAT_ SOCACM_CTL	[7:0]	BATCAP	_AGE[1:0]	BATCAP	_TEMP[1:0] Res		erved	EN_ BATCAP_ TEMP	EN_ BATCAP_ AGE
0x23	BAT_ SOCACM_H	[7:0]	BAT_SOCACM[11:4]							
0x24	BAT_ SOCACM_L	[7:0]		BAT_SC	DCACM[3:0]	Reserved				
0x25	VBAT_READ_H	[7:0]	VBAT_READ[12:5]							
0x26	VBAT_READ_L	[7:0]	VBAT_READ[4:0]				Reserved			
0x27	FUEL_ GAUGE_MODE	[7:0]	SOC_LOW_TH[1:0]		SLP_0	SLP_CURR[1:0]		SLP_TIME[1:0]		EN_FG
0x28	SOC_RESET	[7:0]	SOC_ RESET							
0x29	Buck Configure	[7:0]	BUCK_SS[1:0]		BUCK_ILIM[1:0]		BUCK_ MODE	STP_ BUCK	DISCHG_ BUCK	EN_BUCK
0x2A	Buck Output Voltage Setting	[7:0]	BUCK_	DLY[1:0]		VOUT_BUCK[5:0]				
0x2B	Buck Boost Configure	[7:0]	BUCKBST_SS[1:0]		BUCKBST_ILIM[2:0]		STP_ BUCKBST	DISCHG_ BUCKBST	EN_ BUCKBST	
0x2C	Buck Boost Output Voltage Setting	[7:0]	BUCKBST_DLY[1:0]		VOUT_BUC			KBST[5:0]		
0x2D	Supervisory Setting	[7:0]	VOUT1_ RST	VOUT2_ RST	RESET_ TIME	WD_TI	ME[1:0]	EN_WD	EN_MR_ SD	RESET_WD
0x2E	Fault	[7:0]	BAT_UV	BAT_OC	BAT_ CHGOC	BAT_CHGOV	Reserved	WD_ TIMEOUT	Reserved	TSD110
0x2F	PGOOD_ STATUS	[7:0]	Reserved		MR_PRESS	CHG_CMPLT	VBUSOK	BATOK	VOUT2OK	VOUT10K
0x30	PGOOD1_ MASK	[7:0]	PG1_REV Rese		erved	CHGCMPLT_ MASK1	VBUSOK_ MASK1	BATOK_ MASK1	VOUT2OK_ MASK1	VOUT1OK_ MASK1
0x31	PGOOD2_	[7:0]	PG2_REV	Res	erved	CHGCMPLT_ MASK2	VBUSOK_ MASK2	BATOK_ MASK2	VOUT2OK_ MASK2	VOUT1OK_ MASK2

Address (Hex)	Register Name	Bits	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
0x32	INTERRUPT_ ENABLE1	[7:0]	EN_ SOCLOW_ INT	EN_ SOCACM_ INT	en_ Adpichg_ Int	EN_ BATPRO_INT	EN_THR_ INT	EN_BAT_ INT	EN_CHG_ INT	EN_ VBUS_INT
0x33	INTERRUPT_ ENABLE2	[7:0]	EN_MR_ INT	EN_WD_ INT	EN_ BUCKPG_ INT	EN_ BUCKBSTPG_ INT	Reserved			
0x34	INTERRUPT_ FLAG1	[7:0]	SOCLOW_ INT	SOCACM_ INT	ADPICHG_ INT	BATPRO_INT	THR_INT	BAT_INT	CHG_INT	VBUS_INT
0x35	INTERRUPT_ FLAG2	[7:0]	MR_INT	WD_INT	BUCKPG_ INT	BUCKBSTPG_ INT	Reserved			
0x36	SHIPMODE	[7:0]				Reserved				en_ Shipmode

## Table 18. Manufacturer and Model ID, Address 0x00 Bit Descriptions

Bit(s)	Bit(s) Bit Name Access Default		Default	Description	
[7:4]	MANUF[3:0]	R	0001	The 4-bit manufacturer identification bus.	
[3:0]	MODEL[3:0]	R	0000	The 4-bit model identification bus.	

## Table 19. Silicon Revision, Address 0x01 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:4]	Reserved	R	Not applicable	Reserved.
[3:0]	REV[3:0]	R	1000	The 4-bit silicon revision identification bus.

## Table 20. CHARGER\_VBUS\_ILIM, Address 0x02 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:5]	VADPICHG[2:0]	R/W	100 = 4.6 V	Adaptive Current Limit to VBUS Voltage Threshold Programming. The current to the VBUS voltage threshold can be limited to the following programmed values:
				010 = 4.4 V.
				011 = 4.5 V.
				100 = 4.6 V.
				101 = 4.7 V.
				110 = 4.8 V.
				111 = 4.9 V.
4	Reserved	R	Not applicable	Reserved.
3	VSYSTEM	R/W	$0 = V_{TRM} + 200 \text{ mV}$	VSYS Voltage Programming.
				$0 = V_{TRM} + 200 \text{ mV}.$
				1 = 5 V.
[2:0]	ILIM[2:0]	R/W	001 = 100 mA	VBUS Pin Input Current-Limit Programming Bus. The current into the VBUS pin can be limited to the following programmed values:
				000 = 50 mA.
				001 = 100 mA.
				010 = 150 mA.
				011 = 200 mA.
				100 = 250 mA.
				101 = 300 mA.
				110 = 400 mA.
				111 = 500 mA.

# ADP5360

Bit(s)	Bit Name	Access	Default	Description
[7:2]	VTRM[5:0]	R/W	Factory set	Termination Voltage Programming Bus. The values of the float voltage can be
			-	programmed by using the following values:
				000000 = 3.56 V.
				000001 = 3.58 V.
				000010 = 3.60 V.
				000011 = 3.62 V.
				000100 = 3.64 V.
				000101 = 3.66 V.
				000110 = 3.68 V.
				000111 = 3.70 V.
				001000 = 3.72 V.
				001001 = 3.74 V.
				001010 = 3.76 V.
				001011 = 3.78 V.
				001100 = 3.80 V.
				001101 = 3.82 V.
				001110 = 3.84 V.
				001111 = 3.86 V.
				010000 = 3.88 V.
				010001 = 3.90 V.
				010010 = 3.92 V.
				010011 = 3.94 V.
				010100 = 3.96 V.
				010101 = 3.98 V.
				010110 = 4.00 V.
				010111 = 4.02 V.
				011000 = 4.04 V.
				011001 = 4.06 V.
				011010 = 4.08 V.
				011011 = 4.10 V.
				011100 = 4.12 V.
				011101 = 4.14 V.
				011110 = 4.16 V.
				011111 = 4.18 V.
				10000 = 4.20 V.
				100001 = 4.22 V.
				100010 = 4.24 V.
				100011 = 4.26  V.
				100100 = 4.28 V.
				100101 = 4.30  V.
				100110 = 4.32 V.
				100111 = 4.34 V.
				101000 = 4.36 V.
				101001 = 4.38  V.
				101010 = 4.40  V.
				101011 = 4.42 V.
				101100 = 4.44 V.
				101101 = 4.46  V.
				101110 = 4.48  V.
				101111 = 4.50  V.

## Table 21. CHARGER\_TERMINATION\_SETTING, Address 0x03 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
				110000 = 4.52 V.
				110001 = 4.54 V.
				110010 = 4.56 V.
				110011 = 4.58 V.
				110100 = 4.60 V.
				110101 = 4.62 V.
				110110 = 4.64 V.
				110111 to 111111 = 4.66 V.
[1:0]	ITRK_DEAD[1:0]	R/W	10 = 5 mA	Trickle and Weak Charge Current Programming Bus. The values of the trickle and weak charge currents can be programmed by using the following values:
				00 = 1 mA.
				01 = 2.5 mA.
				10 = 5 mA.
				11 = 10 mA.

Table 22. CHARGER	CUDDENIT	SETTING	Address (	w04 Bit Description	20
Table 22. UNARGER	_CUKKENI_	_SETTING,	Address	JX04 DIL Description	15

Bit(s)	Bit Name	Access	Default	Description
[7:5]	IEND[2:0]	R/W	001 = 5 mA	Termination Current Programming Bus. The values of the termination current can be programmed by using the following values:
				001 = 5 mA.
				010 = 7.5 mA.
				011 = 12.5 mA.
				100 = 17.5 mA.
				101 = 22.5 mA.
				110 = 27.5 mA.
				111 = 32.5 mA.
[4:0]	ICHG[4:0]	R/W	01001 = 100 mA	Fast Charge Current Programming Bus. The values of the constant current charge can be programmed by using the following values:
				00000 = 10 mA.
				00001 = 20 mA.
				00010 = 30 mA.
				00011 = 40 mA.
				00100 = 50 mA.
				00101 = 60 mA.
				00110 = 70 mA.
				00111 = 80 mA.
				01000 = 90 mA.
				01001 = 100 mA.
				01010 = 110 mA.
				01011 = 120 mA.
				01100 = 130 mA.
				01101 = 140 mA.
				01110 = 150 mA.
				01111 = 160 mA.
				10000 = 170 mA.
				10001 = 180 mA.
				10010 = 190 mA.
				10011 = 200 mA.
				10100 = 210 mA.
				10101 = 220 mA.
				10110 = 230 mA.

Bit(s)	Bit Name	Access	Default	Description
				10111 = 240 mA.
				11000 = 250 mA.
				11001 = 260 mA.
				11010 = 270 mA.
				11011 = 280 mA.
				11100 = 290 mA.
				11101 = 300 mA.
				11110 = 310 mA.
				11111 = 320 mA.

Bit(s)	Bit Name	Access	Default	Description
7	DIS_RCH		0 = Enable recharge	Recharge Function Disable.
				0 = recharge enable.
				1 = recharge disable.
[6:5]	VRCH[1:0]	R/W	01 = 120 mV	Recharge Voltage Programming Bus. The values of the recharge threshold can be programmed by using the following values:
				01 = 120 mV.
				10 = 180 mV.
				11 = 240 mV.
[4:3]	VTRK_DEAD[1:0]	R/W	01 = 2.5 V	Trickle to Fast Charge Dead Battery Voltage Programming Bus. The values of the trickle to fast charge threshold can be programmed by using the following values:
				00 = 2.0 V.
				01 = 2.5 V.
				10 = 2.6 V.
				11 = 2.9 V.
[2:0]	VWEAK[2:0]	R/W	011 = 3.0 V	Weak Battery Voltage Rising Threshold. The values of the battery voltage can be programmed by using the following values:
				000 = 2.7 V.
				001 = 2.8 V.
				010 = 2.9 V.
				011 = 3.0 V.
				100 = 3.1 V.
				101 = 3.2 V.
				110 = 3.3 V.
				111 = 3.4 V.

## Table 24. CHARGER\_TIMER\_SETTING, Address 0x06 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:4]	Reserved	R	Not applicable	Reserved.
3	EN_TEND	R/W	0	When low, this bit disables the charge complete timer ( $t_{END}$ ), and a 32 ms deglitch timer ( $t_{DG}$ ) remains on this function.
2	EN_CHG_TIMER	R/W	1	When high, the trickle charge timer ( $t_{TRK}$ ) and the fast charge timer ( $t_{CHG}$ ) are enabled. When low, $t_{TRK}$ and $t_{CHG}$ are disabled.
[1:0]	CHG_TMR_PERIOD[1:0]	R/W	11	t <sub>TRK</sub> and t <sub>CHG</sub> Period.
				00 = 15 minutes/150 minutes.
				01 = 30 minutes/300 minutes.
				10 = 45 minutes/450 minutes.
				11 = 60 minutes/600 minutes.

## Table 25. CHARGER\_FUNCTION\_SETTING, Address 0x07 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
7	EN_JEITA	R/W	0	When low, this bit disables the JEITA Li-Ion temperature battery charging specification.
6	ILIM_JEITA_COOL	R/W	0	When in temperature cool mode, select the battery charging current.
				0 = approximately 50% of programmed charge current.
				1 = approximately 10% of programmed charge current.
5	Reserved	R/W	Not applicable	Reserved.
4	OFF_ISOFET	R/W	0	When high, ISOFET is forced to turn off, and VSYS is shut down only when the battery is present.
3	EN_LDO	R/W	1	When low, the charge LDO is disabled. When high, the charge LDO is enabled.
2	EN_EOC	R/W	1	When high, end of charge is allowed.
1	EN_ADPICHG	R/W	0	When high, the VBUS adaptive current-limit function is enabled during charging. When low, the VBUS adaptive current-limit function is disabled during charging.
0	EN_CHG	R/W	Factory set	When low, charging is disabled. When high and EN_LDO = high, charging is enabled.

## Table 26. CHARGER\_STATUS1, Address 0x08 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description	
7	VBUS_OV	R	Not applicable When high, this bit indicates that the VBUS voltage is over the threshold o		
				Vvbus_ok.	
6	ADPICHG	R	Not applicable When high, this bit indicates that the adaptive charge current is active.		
5	VBUS_ILIM	R	Not applicable When high, this bit indicates that the current into the VBUS pin is limited by the high voltage blocking FET and that the charger is not running at the full programmed I <sub>CHG</sub> .		
[4:3]	Reserved	R	Not applicable	ot applicable Reserved.	
[2:0]	CHARGER_STATUS[2:0]	R	Not applicable	Charger Status Bus. The following values are indications for the charger status:	
				000 = off.	
				001 = trickle charge.	
				010 = fast charge (constant current mode).	
				011 = fast charge (constant voltage mode).	
				100 = charge complete.	
				101 = LDO mode.	
				110 = trickle or fast charge timer expired.	
				111 = battery detection.	

## Table 27. CHARGER\_STATUS2, Address 0x09 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:5]	THR_STATUS[2:0]	R	Not applicable THR Pin Status. The following values are indications for the THR pin NTC resistor value:	
				000 = off.
				001 = battery cold.
				010 = battery cool.
				011 = battery warm.
				100 = battery hot.
				111 = thermistor okay.
4	BAT_OV_STATUS	R	Not applicable	Battery Overvoltage Status.
				0 = no battery overvoltage protection.
				1 = battery overvoltage protection.
3	BAT_UV_STATUS	R	Not applicable	Battery Undervoltage Status.
				0 = no battery undervoltage protection.
				1 = battery undervoltage protection.

Bit(s)	Bit Name	Access	Default Description	
[2:0]	BAT_CHG_STATUS[2:0]	R	Not applicable Battery Status Bus. The following values are indications for battery status:	
				000 = normal.
				001 = no battery.
				010 = V <sub>BSNS</sub> < V <sub>TRK_DEAD</sub> when in charge.
				$011 = V_{TRK} \le V_{BSNS} < V_{WEAK}$ when in charge.
				$100 = V_{BSNS} \ge V_{WEAK}$ when in charge.

#### Table 28. BATTERY\_THERMISTOR\_CONTROL, Address 0x0A Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description	
[7:6]	ITHR[1:0]	R/W	Factory set	Select Battery Thermistor NTC Resistance. The following values are the program values for the battery thermistor NTC resistance:	
				$00 = 60 \ \mu A.$	
				01 = 12 μΑ.	
				10, 11 = 6 μA.	
[5:1]	Reserved	R	Not applicable	Reserved.	
0	EN_THR	R/W	0	When high, the ITHR current source is enabled even when the voltage at the VBUS pin is lower than $V_{\text{VBUS}\_OK}.$	

#### Table 29. THERMISTOR\_60C Threshold, Address 0x0B Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description	
[7:0]	TEMP_HIGH_60[7:0]	R/W	0x56	Thermistor Voltage Threshold for 60°C.	
			THERMISTOR_60C Voltage Threshold (V) = (TEMP_HIGH_60 $\times$ 0.002) (V)		

#### Table 30. THERMISTOR\_45C Threshold, Address 0x0C Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description	
[7:0]	TEMP_HIGH_45[7:0]	R/W	0x8F	Thermistor Voltage Threshold for 45°C	
				THERMISTOR_45C Voltage Threshold (V) = (TEMP_HIGH_45 $\times$ 0.002) (V)	

#### Table 31. THERMISTOR\_10C Threshold, Address 0x0D Bit Descriptions

Bit(s)	Bit Name	Access	Default	Default Description	
[7:0]	:0] TEMP_LOW_10[7:0] R/W 0x71		0x71	Thermistor Voltage Threshold for 10°C	
				THERMISTOR_10C Voltage Threshold (V) = (TEMP_LOW_10 $\times$ 0.01) (V)	

## Table 32. THERMISTOR\_0C Threshold, Address 0x0E Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description	
[7:0]	TEMP_LOW_0[7:0]	R/W	0xB4	Thermistor Voltage Threshold For 0°C	
				THERMISTOR_0C Voltage Threshold (V) = (TEMP_LOW_0 $\times$ 0.01) (V)	

## Table 33. THR\_VOLTAGE Low, Address 0x0F Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:0]	THR_V_LOW[7:0]	R	Not applicable	8-Bit Thermistor Node Voltage Low (mV)
				NTC = THR_V_x[11:0]/ITHR ( $k\Omega$ )

## Table 34. THR\_VOLTAGE High, Address 0x10 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:4]	Reserved	R	Not applicable	Reserved
[3:0]	THR_V_HIGH[11:8]	R	Not applicable	4-Bit Thermistor Node Voltage High (mV)
			,, ,, ,,	NTC = THR_V_x[11:0]/ITHR ( $k\Omega$ )

Bit(s)	Bit Name	Access	Default	Description	
[7:5]	Reserved	R	Not applicable	Reserved.	
4	ISOFET_OVCHG	R/W	0	When low, ISOFET turns on when the battery charging overvoltage protection is triggered. When high, the ISOFET turns off when the battery charging overvoltage protection is triggered.	
3	OC_DIS_HICCUP	R/W	0	Battery Discharge Overcurrent Protection Mode Selection.	
				0 = latch up.	
				1 = hiccup.	
2	OC_CHG_HICCUP	R/W	0 Battery Charge Overcurrent Protection Mode Selection.		
				0 = latch up.	
				1 = hiccup.	
1	EN_CHGLB	R/W	1	When low, the battery charge is not allowed with the battery undervoltage protection triggered. When high, the battery charge is allowed with the battery undervoltage protection triggered.	
0	EN_BATPRO	R/W	Factory set	When low, the battery protection function is disabled. When high, the battery protection function is enabled.	

## Table 35. Battery Protection Control, Address 0x11 Bit Descriptions

Table 36. Battery Protection Un	ndervoltage Setting, Address	0x12 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:4]	UV_DISCH[3:0]	R/W	Factory set	Battery Undervoltage Protection Threshold. The values of the battery undervoltage
				protection threshold can be programmed by using the following values:
				0000 = 2.05 V.
				0001 = 2.10 V.
				0010 = 2.15 V.
				0011 = 2.20 V.
				0100 = 2.25 V.
				0101 = 2.30 V.
				0110 = 2.35 V.
				0111 = 2.40 V.
				1000 = 2.45 V.
				1001 = 2.50 V.
				1010 = 2.55 V.
				1011 = 2.60 V.
				1100 = 2.65 V.
				1101 = 2.70 V.
				1110 = 2.75 V.
				1111 = 2.80 V.
[3:2]	HYS_UV_DISCH[1:0]	R/W	00 = 2%	Battery Undervoltage Protection for Overdischarge Hysteresis. The values of the battery undervoltage protection can be programmed byusing the following values:
				00 = 2% UV_DISCH voltage threshold.
				01 = 4% UV_DISCH voltage threshold.
				10 = 6% UV_DISCH voltage threshold.
				11 = 8% UV_DISCH voltage threshold.
[1:0]	DGT_UV_DISCH[1:0]	R/W	00 = 30 ms	Battery Undervoltage Protection Deglitch Time. The values of the battery undervoltage protection deglitch time can be programmed by using the following values:
				00 = 30 ms.
				01 = 60 ms.
				10 = 120 ms.
				11 = 240 ms.

Bit(s)	Bit Name	Access	Default	Description
[7:5]	OC_DISCH[2:0]	R/W	Factory set	Battery Overcurrent Protection for Overdischarge Threshold. The values of the battery overcurrent protection can be programmed by using the following values:
				000 = 50 mA.
				001 = 100 mA.
				010 = 150 mA.
				011 = 200 mA.
				100 = 300 mA.
				101 = 400 mA.
				110 = 500 mA.
				111 = 600 mA.
4	Reserved	R	Not applicable	Reserved
[3:1]	DGT_OC_DISCH[2:0]	R/W	011 = 5 ms	Battery Discharge Overcurrent Protection Deglitch Time Setting. The values of the battery discharge overcurrent protection can be programmed by using the following values:
				001 = 0.5 ms.
				010 = 1 ms.
				011 = 5 ms.
				100 = 10 ms.
				101 = 20 ms.
				110 = 50 ms.
				111 = 100 ms.
0	Reserved	R	Not applicable	Reserved

## Table 37. Battery Protection Overcharge Setting, Address 0x13 Bit Descriptions

## Table 38. Battery Protection Overvoltage Setting, Address 0x14 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:3]	OV_CHG[4:0]	R/W	Factory set	Battery Overvoltage Protection Threshold. The values of the battery overvoltage protection threshold can be programmed by using the following values:
				00000 = 3.55  V.
				00001 = 3.60  V.
				00010 = 3.65  V.
				00011 = 3.70 V.
				00100 = 3.75 V.
				00101 = 3.80 V.
				00110 = 3.85 V.
				00111 = 3.90 V.
				01000 = 3.95 V.
				01001 = 4.00 V.
				01010 = 4.05 V.
				01011 = 4.10 V.
				01100 = 4.15 V.
				01101 = 4.20 V.
				01110 = 4.25 V.
				01111 = 4.30 V.
				10000 = 4.35 V.
				10001 = 4.40 V.
				10010 = 4.45 V.
				10011 = 4.50 V.

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Bit(s)	Bit Name	Access	Default	Description
				10100 = 4.55 V.
				10101 = 4.60 V.
				10110 = 4.65 V.
				10111 = 4.70 V.
				11000 = 4.75 V.
				11001 to 11111 = 4.80 V.
[2:1]	HYS_OV_CHG[1:0]	R/W	00	Battery Overvoltage Protection for Charge Hysteresis. The values of the battery overvoltage protection can be programmed by using the following values:
				$00 = 2\%$ of the voltage of the OV_CHG threshold.
				01 = 4% of the voltage of the OV_CHG threshold.
				10 = 6% of the voltage of the OV_CHG threshold.
				$11 = 8\%$ of the voltage of the OV_CHG threshold.
0	DGT_OV_CHG	R/W	0 = 0.5 sec	Battery Overvoltage Protection Deglitch Time. The values of the battery overvoltage protection deglitch time can be programmed by using the following values:
				0 = 0.5 sec.
				1 = 1 sec.

Table 39. Battery Protection Charge Overcharge Setting, Address 0x15	Bit Descriptions
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Bit(s)	Bit Name	Access	Default	Description
[7:5]	OC_CHG[2:0]	R/W	Factory set	Battery Overcurrent Protection for Overdischarge Threshold. The values of the battery overcurrent protection can be programmed by using the following values:
				000 = 25 mA.
				001 = 50 mA.
				010 = 100 mA.
				011 = 150 mA.
				100 = 200 mA.
				101 = 250 mA.
				110 = 300 mA.
				111 = 400 mA.
[4:3]	DGT_OC_CHG[1:0]	R/W	01 = 10 ms	Battery Charge Overcurrent Protection Deglitch Time Setting. The values of the battery charge overcurrent protection can be programmed byusing the following values:
				00 = 5 ms.
				01 = 10 ms.
				10 = 20 ms.
				11 = 40 ms.
[2:0]	Reserved	R	Not applicable	Reserved.

## FUEL GAUGE REGISTER BIT DESCRIPTIONS

Table 40. V_SOC_0, Address 0x16 Bit Descriptio	ns
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Bit(s)	Bit Name	Access	Default Description	
[7:0]	V_SOC_0[7:0]	R/W	0x7D	Battery Voltage When State of Charge = 0%. The default voltage is 3.5 V.
				Battery Voltage (V) = $(2.5 + V_SOC_0 \times 0.008)$ (V).

## Table 41. V\_SOC\_5, Address 0x17 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:0]	V_SOC_5[7:0]	R/W	0x91	Battery Voltage When State of Charge = 5%. The default voltage is 3.66 V.
				Battery voltage (V) = $(2.5 + V_SOC_5 \times 0.008)$ (V).

Table 42. V\_SOC\_11, Address 0x18 Bit Descriptions

			211 2 00		-	• .•
Bit(s)	Bit Name		ccess	Default	_	ription
[7:0]	V_SOC_11[7	:0] R/	/W	0x94		ery Voltage When State of Charge = 11%. The default voltage is 3.684 V.
					Batte	ery voltage (V) = $(2.5 + V_SOC_{11} \times 0.008)$ (V).
Table 43	3. V_SOC_19, Add	ress 0x19	Bit Dese	riptions		
Bit(s)	Bit Name	A	ccess	Default	Desc	ription
[7:0]	V_SOC_19[7	':0] R/	/W	0x99	Batte	ery Voltage When State of Charge = 19%. The default voltage is 3.724 V.
					Batte	ery voltage (V) = $(2.5 + V_SOC_{19} \times 0.008)$ (V).
Table 44	I. V_SOC_28, Add	ress 0x1A	Bit Des	criptions	•	
Bit(s)	Bit Name		ccess	Default	Desc	cription
[7:0]	V_SOC_28[7	':0] R/	/W	0x9E		ery Voltage When State of Charge = 28%. The default voltage is 3.764 V.
					Batte	ery Voltage (V) = $(2.5 + V_SOC_{28} \times 0.008)$ (V).
Table 45	5. V_SOC_41, Add	race Ov1B	Rit Dec	crintions		
Bit(s)	Bit Name	1	ccess	Default	Desc	cription
[7:0]	V_SOC_41[7		/W	0xA3		ery Voltage When State of Charge = 41%. The default voltage is 3.804 V.
						ery Voltage (V) = $(2.5 + V_SOC_41 \times 0.008)$ (V).
	1	I		I	Juitt	
Table 46	5. V_SOC_55, Add	ress 0x1C	Bit Des	criptions	1	
Bit(s)	Bit Name	A	ccess	Default	Descr	iption
[7:0]	V_SOC_55[7	:0] R/	/W	0xAB		y Voltage When State of Charge = 55%. The default voltage is 3.868 V.
					Batter	y Voltage (V) = $(2.5 + V_SOC_{55} \times 0.008)$ (V).
Table 47	7. V_SOC_69, Add	ress 0x1D	Bit Des	criptions		
Bit(s)			Description			
[7:0]	V_SOC_69[7	':0] R/	/W	0xB5		y Voltage When State of Charge = 69%. The default voltage is 3.948 V.
		-				y Voltage (V) = $(2.5 + V_SOC_{69} \times 0.008)$ (V).
T.11. 40			<b>D'4</b> D			
Bit(s)	3. V_SOC_84, Add Bit Name		ccess	Default	Descr	iption
[7:0]	V_SOC_84[7		/W	0xC4		y Voltage When State of Charge = 84%. The default voltage is 4.068 V.
[1.0]	v_30C_04[/	.51	**	0.04		$y$ Voltage (V) = (2.5 + V_SOC_84 × 0.008) (V).
	I	I			Datter	y voltage (v) = (2.5 + v_50C_0+ × 0.000) (v).
Table 49	0. V_SOC_100, Ad	dress 0x1H	Bit De	scriptions		
Bit(s)	Bit Name	A	ccess	Default	Descr	iption
[7:0]	V_SOC_100	[7:0] R/	/W	0xD5	Batter	y Voltage When State of Charge = 100%. The default voltage is 4.204 V.
					Batter	$vy$ Voltage (V) = (2.5 + V_SOC_100 × 0.008) (V).
Tabla 50	). BAT_CAP, Addı	·acc ()+20 I	Sit Dece	rintions		
	Bit Name		ccess	Default		Description
Bit(s) [7:0]	BIT Name BAT_CAP[7:0		w /W	0x32		Battery Capacity Input
[7.0]		K/	vv	0232		Battery Capacity input Battery Capacity = $(BAT_CAP \times 2)$ mAh
	I			L		Dattery Capacity – (DAI_CAF X 2) IIIAII
Table 51	. BAT_SOC, Addr	ess 0x21 H	Bit Desc	riptions		
Bit(s)	Bit Name	Access	Defa	ult	De	escription
7	Reserved	R	Not	pplicable	Ro	served

514(5)	Ditituille	110005	Delaut	Description
7	Reserved	R	Not applicable	Reserved
[6:0]	BAT_SOC[6:0]	R	Not applicable	Battery State of Charge Output
				State of Charge = BAT_SOC %, Only Valued Between 0% to 100%

## Table 52. BAT\_SOCACM\_CTL, Address 0x22 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:6]	BATCAP_AGE[1:0]	R/W	01 = 1.5%	Battery Capacity Reduction Percentage When BAT_SOCACM Overflows.
				00 = 0.8 %.
				01 = 1.5 %.
				10 = 3.1 %.
				11 = 6.3 %.
[5:4]	BATCAP_TEMP[1:0]	R/W	00 = 0.2%/°C	Battery Capacity Compensation with Temperature Coefficient. The values of the battery capacity compensation can be programmed by using the following values:
				00 = 0.2 %/°C.
				01 = 0.4 %/°C.
				10 = 0.6 %/°C.
				11 = 0.8 %/°C.
[3:2]	Reserved		Not applicable	Reserved.
1	EN_BATCAP_TEMP	R/W	0	Battery Capacity Temperature Compensation Function Selection.
				0 = disable battery capacity temperature compensation.
				1 = enable battery capacity temperature compensation.
0	EN_BATCAP_AGE	R/W	0	Battery Capacity Aging Compensation Function Selection.
				0 = disable battery capacity aging automatic adjustment.
				1 = enable battery capacity aging automatic adjustment.

## Table 53. BAT\_SOCACM\_H, Address 0x23 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:0]	BAT_SOCACM[11:4]	R	Not applicable	Highest Eight Bits of an 8-Bit Accumulation of the Charge State
				Number of Times for Charging = BAT_SOCACM[11:0]/100

## Table 54. BAT\_SOCACM\_L, Address 0x24 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:4]	BAT_SOCACM[3:0]	R	Not applicable	Lowest Four Bits of a 4-Bit Accumulation of the Charge State
				Number of Times for Charging = BAT_SOCACM[11:0]/100
[3:0]	Reserved	R	Not applicable	Reserved

## Table 55. VBAT\_READ\_H, Address 0x25 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:0]	VBAT_READ[12:5]	R	Not applicable	Battery Voltage Reading of the Highest Eight Bits (mV)

## Table 56. VBAT\_READ\_L, Address 0x26 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:3]	VBAT_READ[4:0]	R	Not applicable	Battery Voltage Reading of the Lowest Five Bits (mV)
[2:0]	Reserved	R	Not applicable	Reserved

## Table 57. FUEL\_GAUGE\_MODE, Address 0x27 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:6]	SOC_LOW_TH[1:0]	R/W	01 = 11%	Indication of Low State of Charge Threshold
				00 = 6%
				01 = 11%
				10 = 21%
				11 = 31%
[5:4]	SLP_CURR[1:0]	R/W	01 = 10 mA	Fuel Gauge Sleep Mode Current Threshold
				00 = 5 mA
				01 = 10 mA
				10 = 20 mA
				11 = 40 mA

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Bit(s)	Bit Name	Access	Default	Description
[3:2]	SLP_TIME[1:0]	R/W	00 = 1 min	Fuel Gauge Update Rate Of The Sleep Mode
				00 = 1 min
				01 = 4 min
				10 = 8 min
				11 = 16 min
1	FG_MODE	R/W	0	Fuel Gauge Operation Mode Selection
				1 = operate in sleep mode
				0 = operate in active mode
0	EN_FG	R/W	0	Fuel Gauge Function Selection
				0 = disable fuel gauge
				1 = enable fuel gauge

## Table 58. SOC\_RESET, Address 0x28 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
7	SOC_RESET	W	0	Write 1, then write 0 to refresh the BAT_SOC, VBAT_READ_H, and VBAT_READ_L registers.
[6:0]	Reserved	R	Not applicable	Reserved.

## SWITCHING REGULATOR REGISTER BIT DESCRIPTIONS

#### Table 59. Buck Configure, Address 0x29 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:6]	BUCK_SS[1:0]	R/W	Factory set	Buck Regulator Output Soft Start Time. The values of the soft start time can be programmed by using the following values:
				00 = 1 ms.
				01 = 8 ms.
				10 = 64  ms.
				11 = 512 ms.
[5:4]	BUCK_ILIM[1:0]	R/W	11 = 400 mA	Buck Regulator Peak Current Limit. The values of the peak current
				limit can be programmed by using the following values:
				00 = 100 mA.
				01 = 200 mA.
				10 = 300 mA.
				11 = 400 mA.
3	BUCK_MODE	R/W	Factory set	Buck Operate Mode Selection.
				0 = hystersis mode.
				1 = FPWM mode.
2	STP_BUCK	R/W	0 = disable	Enable Stop Feature to Buck Regulator.
				0 = disable pulse stop feature.
				1 = enable pulse stop feature.
1	DISCHG_BUCK	R/W	Factory set	Configure Output Discharge Functionality for Buck.
				0 = disable output discharge function.
				1 = enable output discharge function.
0	EN_BUCK	R/W	Factory set	Buck Output Control.
				0 = disable buck output.
				1 = enable buck output.

Bit(s)	Bit Name	Access	Default	Description
[7:6]	BUCK_DLY[1:0]	R/W	$00 = 0 \ \mu s$	Buck Switch Delay Time in Hystersis. The values of the delay time can be programmed by using the following values:
				00 = 0 μs. 01 = 5 μs.
				$10 = 10 \ \mu s.$
_				$11 = 20 \ \mu s.$
[5:0]	VOUT_BUCK[5:0]	R/W	Factory set	Buck Output Voltage Setting. The values of the voltage setting can be programmed by using the following values:
				000000 = 0.6 V.
				000001 = 0.65 V.
				111111 = 3.75 V.

## Table 60. Buck Output Voltage Setting, Address 0x2A Bit Descriptions

## Table 61. Buck Boost Configure, Address 0x2B Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:6]	7:6] BUCKBST_SS[1:0] R/W	R/W	Factory set	Buck Boost Regulator Output Soft Start Time. The values of the start time can be programmed by using the following values:
				00 = 1 ms.
				01 = 8 ms.
				10 = 64 ms.
				11 = 512 ms.
[5:3]	BUCKBST_ILIM[2:0]	R/W	011 = 400 mA	Buck Boost Regulator Peak Current Limit. The values of the peak current limit can be programmed by using the following values:
				000 = 100 mA.
				001 = 200 mA.
			010 = 300 mA.	
				011 = 400 mA.
				100 = 500 mA.
				101 = 600 mA.
				110 = 700 mA.
				111 = 800 mA.
2	STP_BUCKBST	R/W	0 = disable	Enable Stop Feature to Buck Boost Regulator.
				0 = disable pulse stop feature.
				1 = enable pulse stop feature.
1	DISCHG_BUCKBST	R/W	Factory set	Configure Output Discharge Functionality for Buck Boost.
				0 = disable output discharge function.
				1 = enable output discharge function.
0	EN_BUCKBST	R/W	Factory set	Buck Boost Output Control.
				0 = disable buck boost output.
				1 = enable buck boost output.

## Table 62. Buck Boost Output Voltage Setting, Address 0x2C Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:6]	BUCKBST_DLY[1:0]	R/W	$00 = 0 \ \mu s$	Buck Boost Switch Delay Time in Hystersis. The values of the delay time can be programmed by using the following values:
				00 = 0 μs.
				01 = 5 μs.
				10 = 10 μs.
				$11 = 20 \ \mu s.$

Bit(s)	Bit Name	Access	Default	Description
[5:0]	VOUT_BUCKBST[5:0]	R/W	Factory set	Buck Boost Output Voltage Setting. The values of the voltage setting can be programmed by using the following values:
				000000 = 1.8 V with 100 mV step.
				000001 = 1.9 V with 100 mV step.
				001011 = 2.9 V with 100 mV step.
				001100 = 2.95 V with 50 mV step.
				111111 = 5.5 V with 50 mV step.

## SUPERVISORY REGISTER BIT DESCRIPTIONS

## Table 63. Supervisory Setting, Address 0x2D Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description	
7	VOUT1_RST	R/W	1	Buck Output Voltage Monitor to RESET Selection.	
				0 = disable buck voltage monitor to RESET.	
				1 = enable buck voltage monitor to RESET.	
6	VOUT2_RST	R/W	0	Buck Boost Output Voltage Monitor to RESET Selection.	
				0 = disable buck boost voltage monitor to RESET.	
				1 = snable buck boost voltage monitor to RESET.	
5	RESET_TIME	R/W	0 = 200 ms	RESET Timeout Period Selection. The values of the period selection can be programmed	
				by using the following values:	
				0 = 200 ms.	
				1 = 1.6 sec.	
[4:3]	WD_TIME[1:0]	R/W	00 = 12.5 sec	Watchdog Timeout Period Selection. The values of the period selection can be	
				programmed by using the following values: 00 = 12.5 sec.	
				01 = 25.6 sec.	
				10 = 50 sec.	
				11 = 100 sec.	
2	EN_WD	R/W	0 = disable	When high, the watchdog timer function is enabled. When low, the watchdog timer function is disabled.	
1	EN_MR_SD	R/W	0 = disable	When high, the device enters shipment mode after MR presses low for 12 sec. When	
				low, disable MR to enter shipment mode.	
0	RESET_WD	W	0	When high, the watchdog safety timer resets. The RESET_WD bit is reset automatically.	

## STATUS AND FAULT REGISTER BIT DESCRIPTIONS

#### Table 64. Fault, Address 0x2E Bit Descriptions<sup>1</sup>

Bit(s)	Bit Name	Access	Default	Description
7	BAT_UV <sup>1</sup>	R/W	0	When high, this bit indicates that the battery is undervoltage when overdischarging.
6	BAT_OC <sup>1</sup>	R/W	0	When high, this bit indicates that the battery is overcurrent during overdischarge.
5	BAT_CHGOC <sup>1</sup>	R/W	0	When high, this bit indicates that the battery is overcurrent during overcharge.
4	BAT_CHGOV <sup>1</sup>	R/W	0	When high, this bit indicates that the battery is overvoltage during overcharge.
3	Reserved	R	Not applicable	Reserved.
2	WD_TIMEOUT <sup>1</sup>	R/W	0	When high, watchdog timeout occurred.
1	Reserved	R/W	0	Reserved.
0	TSD110 <sup>1</sup>	R/W	0	When high, the temperature shutdown fault occurs.

<sup>1</sup> To reset the fault bits in the fault register, cycle power on the VBUS pin or write high to the corresponding bits of the fault register.

Bit(s) **Bit Name** Access Default Description Reserved [7:6] R Not applicable Reserved. MR\_PRESS 5 R Not applicable When high, this bit indicates that the  $\overline{MR}$  pin is pulled to low after t<sub>DG</sub>. 4 R CHG\_CMPLT Not applicable This bit shows battery charge complete. 0 = the charger is not in charge complete status. 1 = the charger is in charge complete status. 3 VBUSOK R Not applicable This bit shows the real-time status of the VBUS pin voltage. 0 = the voltage of the VBUS pin is lower than  $V_{VBUS_OK}$  or higher than  $V_{VBUS_OV}$ . 1 = the voltage of the VBUS pin is higher than V<sub>VBUS\_OK</sub> and lower than V<sub>VBUS\_OV</sub>. 2 BATOK R Not applicable This bit shows the real-time status of the battery voltage. This bit is only active when the fuel gauge function is enabled.  $0 = battery voltage is less than V_{WEAK}$ .  $1 = battery voltage is more than V_{WEAK}$ . 1 VOUT2OK This bit shows real-time power good status for the buck boost regulator. This bit is only R Not applicable effective in buck boost standalone fixed output mode. 0 = buck boost regulator power-good status is low. 1 = buck boost regulator power-good status is high. 0 VOUT10K R Not applicable This bit shows real-time power-good status for the buck regulator. This bit is not effective if the buck is configured as load switch mode. 0 = buck power-good status is low. 1 = buck power-good status is high.

#### Table 65. PGOOD\_STATUS Register, Address 0x2F Bit Descriptions

#### Table 66. PGOOD1\_MASK Register, Address 0x30 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
7	PG1_REV	R/W	Factory set	This bit configures the active low output of the PGOOD1 pin.
				0 = disable active low.
				1 = enable active low.
[6:5]	Reserved		Not applicable	Reserved.
4	CHGCMPLT_MASK1	R/W	0	This bit configures the external PGOOD1 pin.
				0 = does not send the output charger complete signal to the external PGOOD1 pin.
				1 = sends the output charger complete signal to the external PGOOD1 pin.
3	VBUSOK_MASK1	R/W	Factory set	This bit configures the external PGOOD1 pin.
				0 = does not send the output VBUS voltage status signal to the external PGOOD1 pin.
				1 = sends the output VBUS voltage status signal to the external PGOOD1 pin.
2	BATOK_MASK1	R/W	0	This bit configures the external PGOOD1 pin.
				0 = does not send the output battery voltage okay signal to the external PGOOD1 pin.
				1 = sends the output battery voltage okay signal to the external PGOOD1 pin.
1	VOUT2OK_MASK1	R/W	0	This bit configures the external PGOOD1 pin for buck boost output.
				0 = does not send the output buck boost PGOOD signal to the external PGOOD1 pin.
				1 = sends the output buck boost PGOOD signal to the external PGOOD1 pin.
0	VOUT1OK_MASK1	R/W	Factory set	This bit configures the external PGOOD1 pin. This bit is not effective if the buck
				is configured in load switch mode.
				0 = does not send the output buck PGOOD signal to the external PGOOD1 pin.
				1 = sends the output buck PGOOD signal to the external PGOOD1 pin.

Bit(s)	Bit Name	Access	Default	Description
7	PG2_REV	R/W	0	This bit configures the active low output of the PGOOD2 pin output.
				0 = disable active low.
				1 = enable active low.
[6:5]	Reserved		Not applicable	Reserved.
4	CHGCMPLT_MASK2	R/W	0	This bit configures the external PGOOD2 pin.
				0 = does not send the output charger complete signal to the external PGOOD2 pin.
				1 = sends the output charger complete signal to the external PGOOD2 pin.
3	VBUSOK_MASK2	R/W	0	This bit configures the external PGOOD2 pin.
				0 = does not send the output VBUS voltage status signal to the external
				PGOOD2 pin.
				1 = sends the output VBUS voltage status signal to the external PGOOD2 pin.
2	BATOK_MASK2	R/W	0	This bit configures the external PGOOD2 pin.
				0 = does not send the output battery voltage okay signal to the external
				PGOOD2 pin.
				1 = sends the output battery voltage okay signal to the external PGOOD2 pin.
1	VOUT2OK_MASK2	R/W	0	This bit configures the external PGOOD2 pin for buck boost output.
				0 = does not send the output buck boost PGOOD signal to the external PGOOD2 pin.
				1 = sends the output buck boost PGOOD signal to the external PGOOD2 pin.
0	VOUT1OK_MASK2	R/W	0	This bit configures the external PGOOD2 pin. This bit is not effective if the buck
				is configured in load switch mode.
				0 = does not send the output buck PGOOD signal to the external PGOOD2 pin.
				1 = sends the output buck PGOOD signal to the external PGOOD2 pin.

## Table 67. PGOOD2\_MASK Register, Address 0x31 Bit Descriptions

## Table 68. INTERRUPT\_ENABLE1 Register, Address 0x32 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
7	EN_SOCLOW_INT	R/W	0	When high, the battery low state of the charge interrupt is allowed.
6	EN_SOCACM_INT	R/W	0	When high, the state of e tcharge accumulation interrupt is allowed.
5	EN_ADPICHG_INT	R/W	0	When high, the VBUS adaptive charge current-limit interrupt is allowed.
4	EN_BATPRO_INT	R/W	0	When high, the battery protection interrupt is allowed.
3	EN_THR_INT	R/W	0	When high, the THR temperature threshold interrupt is allowed.
2	EN_BAT_INT	R/W	0	When high, the battery voltage threshold interrupt is allowed.
1	EN_CHG_INT	R/W	0	When high, the charger mode change interrupt is allowed.
0	EN_VBUS_INT	R/W	0	When high, the VBUS pin voltage threshold interrupt is allowed.

## Table 69. INTERRUPT\_ENABLE2 Register, Address 0x33 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
7	EN_MR_INT	R/W	0	When high, the $\overline{MR}$ press interrupt is allowed.
6	EN_WD_INT	R/W	0	When high, the watchdog alarm interrupt is allowed.
5	EN_BUCKPG_INT	R/W	0	When high, the VOUT1OK change interrupt is allowed.
4	EN_BUCKBSTPG_INT	R/W	0	When high, the VOUT2OK change interrupt is allowed.
[3:0]	Reserved	R/W	Not applicable	Reserved.

Bit(s)	Bit Name	Access	Default	Description
7	SOCLOW_INT <sup>1</sup>	R	Not applicable	When high, this bit indicates an interrupt caused by low battery voltage.
6	SOCACM_INT <sup>1</sup>	R	Not applicable	When high, this bit indicates an interrupt caused by state of charge accumulation to 4096 points and an overflow of points.
5	ADPICHG_INT	R	Not applicable	When high, this bit indicates an interrupt caused by VBUS input current-limit adaptive regulation.
4	BATPRO_INT <sup>1</sup>	R	Not applicable	When high, this bit indicates an interrupt caused by battery protection triggered with battery fault events.
3	THR_INT <sup>1</sup>	R	Not applicable	When high, this bit indicates an interrupt caused by THR temperature thresholds.
2	BAT_INT <sup>1</sup>	R	Not applicable	When high, this bit indicates an interrupt caused by battery voltage thresholds.
1	CHG_INT <sup>1</sup>	R	Not applicable	When high, this bit indicates an interrupt caused by a charger mode change.
0	VBUS_INT <sup>1</sup>	R	Not applicable	When high, this bit indicates an interrupt caused by VBUS voltage threshold.

## Table 70. INTERRUPT\_FLAG1 Register, Address 0x34 Bit Descriptions

<sup>1</sup> When reading the register, the interrupt bit resets automatically.

#### Table 71. INTERRUPT\_FLAG2 Register, Address 0x35 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
7	MR_INT <sup>1</sup>	R	Not applicable	When high, this bit indicates an interrupt caused by the $\overline{\text{MR}}$ press.
6	WD_INT <sup>1</sup>	R	Not applicable	When high, this bit indicates an interrupt caused by the watchdog alarm.
5	BUCKPG_INT <sup>1</sup>	R	Not applicable	When high, this bit indicates an interrupt caused by a VOUT1OK trigger.
4	BUCKBSTPG_INT <sup>1</sup>	R	Not applicable	When high, this bit indicates an interrupt caused by a VOUT2OK trigger.
[3:0]	Reserved	R	Not applicable	Reserved.

<sup>1</sup> When reading the register, the interrupt bit resets automatically.

#### Table 72. SHIPMODE Register, Address 0x36 Bit Descriptions

Bit(s)	Bit Name	Access	Default	Description
[7:1]	Reserved	R	Not applicable	Reserved.
0	EN_SHIPMODE	R/W	0	When high, the ADP5360 enters shipment mode. When low, shipment mode is disabled.

## **APPLICATIONS INFORMATION** TYPICAL APPLICATION CIRCUITS

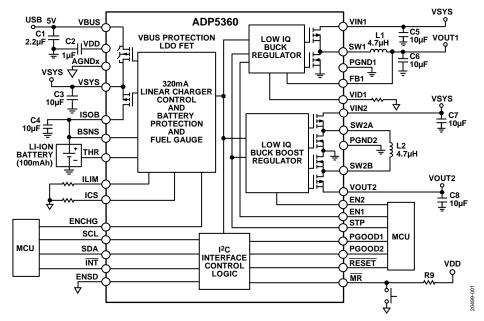


Figure 60. ADP5360 Application Diagram

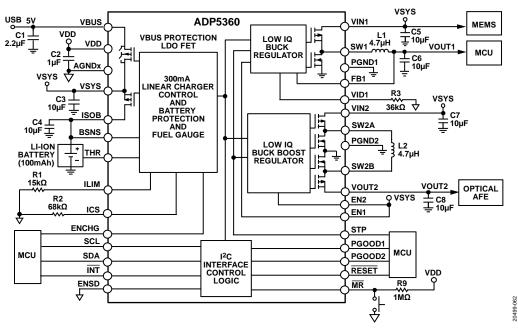


Figure 61. Li-Ion Battery Charger Application in Healthcare Portable

## **EXTERNAL COMPONENTS**

## **VBUS Capacitor Selection**

According to the USB specification, USB peripherals have a detectable change in capacitance on VBUS when VBUS is attached. The peripheral device VBUS bypass capacitance must be at least 1  $\mu$ F but not larger than 10  $\mu$ F. The combined capacitance for the VBUS pin and the VDD pin must not exceed 10  $\mu$ F at any temperature or dc bias condition. Suggested VBUS capacitors are shown in Table 73.

#### Table 73. Suggested VBUS Capacitors

Vendor	Product Number	Value (µF)	Voltage (V)	Size
Murata	GRM155R61E225ME15D	2.2	25	0402
Yageo	CC0402MRX5R8BB225	2.2	25	0402

## **VDD** Capacitor Selection

The internal supply voltage of the ADP5360 is equipped with a noise suppressing capacitor at VDD. Use typical VDD capacitance (1  $\mu$ F). However, do not exceed 10  $\mu$ F during operation. Do not connect any external voltage source, any resistive load, or any other current load to VDD. Suggested VDD capacitors are shown in Table 74.

#### Table 74. Suggested VDD Capacitors

Vendor	Product Number	Value (µF)	Voltage (V)	Size
Murata	GRM155R60J105KE19D	1	6.3	0402
Yageo	CC0402KRX5R5BB105	1	6.3	0402

## **VSYS** Capacitor Selection

To guarantee the performance of the charger in various operation modes, including trickle charge, constant current charge, and constant voltage charge, it is imperative that the effects of dc bias, temperature, and tolerances on the behavior of the capacitors be evaluated for each application. The total VSYS capacitance consists of all capacitors when VSYS is tied together with the input node of the buck and buck boost regulators.

The VSYS capacitance must be  $\geq 10 \ \mu$ F. Suggested VSYS capacities are shown in Table 75.

# Table 75. Suggested VSYS, ISOB, VIN1, VIN2, $V_{\rm OUT1}$ , and VOUT2 Capacitors

Vendor	Product Number	Value (µF)	Voltage (V)	Size
Murata	GRM155R60J106ME44D	10	6.3	0402
Yageo	CC0402MRX5R5BB106	10	6.3	0402

## **ISOB Capacitor Selection**

The ISOB effective capacitance must be  $\ge 4.7 \ \mu\text{F}$  at any point during operation. Typically, a nominal capacitance of 10  $\mu\text{F}$  is required to fulfill the condition at all points of operation. Suggestions for an ISOB capacitor are show in Table 75.

## **Buck Input Capacitor Selection**

An input capacitor is required to reduce the input voltage ripple, input ripple current, and source impedance. Place the input capacitor as close as possible to the VIN1 pin. Use the following equation to determine the rms input current:

$$I_{RMS} \ge I_{LOAD(MAX)} \sqrt{\frac{V_{OUT} \left(V_{IN} - V_{OUT}\right)}{V_{IN}}}$$

For most applications, the VIN1 pin ties together with the VSYS pin. The VSYS capacitance is effective, therefore, a 1  $\mu$ F capacitor is sufficient for the VIN1 pin. The input capacitor can be increased without any limit for better input voltage filtering. Suggested VIN1 capacitors are show in Table 75.

## **Buck Inductor Selection**

The high switching frequency of the ADP5360 buck converter allows the selection of small chip inductors when the buck operates in FPWM mode.

Use the following equation to calculate the peak-to-peak inductor current ripple (I<sub>RIPPLE1</sub>):

$$I_{RIPPLE1} = V_{OUT1} \times ((V_{IN1} - V_{OUT1}))/(V_{IN1} \times f_{SW} \times L1)$$

where:

 $V_{OUT1}$  is the buck output voltage.

 $V_{IN1}$  is the buck input voltage at the VIN1 node.

 $f_{\rm SW}$  is the buck switching frequency.

*L1* is the buck output inductor value.

The minimum dc current rating of the inductor must be greater than the inductor peak current ( $I_{PEAK1}$ ). To calculate  $I_{PEAK1}$ , use the following equation:

 $I_{PEAK1} = I_{LOAD1(MAX)} + I_{RIPPLE1}$ 

where  $I_{LOAD(MAX)}$  is the output current load.

Inductor conduction losses are caused by the flow of current through the inductor, which has an associated internal dc resistance (DCR). Larger inductors have smaller DCR values that can decrease inductor conduction losses. Inductor core losses are related to the magnetic permeability of the core material. Because the buck regulators are high switching frequency dc-todc converters, shielded ferrite core material is recommended for low core losses and low electromagnetic interference (EMI).

Suggested buck inductors are shown in Table 76.

## **Buck Output Capacitor Selection**

Output capacitance is required to minimize the output voltage overshoot and undershoot and to minimize the output ripple significantly both in hysteresis mode and FPWM mode. Capacitors with low equivalent series resistance (ESR) values produce the lowest output ripple in FPWM mode.

Suggested buck output capacitors are shown in Table 75.

## **Buck Boost Input Capacitor Selection**

An input capacitor is required to reduce the input voltage ripple, input ripple current, and source impedance. Place the input capacitor as close as possible to the VIN2 pin.

For most applications, the VIN2 pin ties together with the VSYS pin. The VSYS capacitance is effective, therefore, a 1  $\mu$ F capacitor is sufficient for the VIN2 pin. The input capacitor can be increased without any limit for better input voltage filtering. Suggested VIN2 capacitors are show in Table 75.

## **Buck Boost Inductor Selection**

Inductor conduction losses are caused by the flow of current through the inductor, which has an associated internal DCR. Larger inductors have smaller DCR values that can decrease inductor conduction losses. Inductor core losses are related to the magnetic permeability of the core material.

Suggested buck boost inductors are shown in Table 76.

## **Buck Boost Output Capacitor Selection**

Output capacitance is required to minimize the output voltage overshoot and undershoot and to minimize the output ripple significantly in hysteresis mode.

Suggested buck boost output capacitors are shown in Table 75.

#### Table 76. Recommended Inductors

Vendor	Model	Inductance (µH)	Dimensions (mm)	DCR (mΩ)	Rated Current (I <sub>R</sub> ) (A)
Wurth	74479776247A	4.7	2.0 × 1.6 × 1.0	140	1.2
TDK	MLP2016H4R7	4.7	2.0  imes 1.6  imes 0.85	160	1.1

# **PCB LAYOUT GUIDELINES**

Poor layout can affect ADP5360 performance, causing EMI and electromagnetic compatibility (EMC) problems, ground bounce, and voltage losses, as well as affect regulation and stability. A good layout is implemented using the following guidelines:

- Place the decoupling capacitor, inductor, input capacitor, and output capacitor as close as possible to the ADP5360.
- Use a ground plane with several vias connecting to the component side ground to further reduce noise interference on sensitive circuit nodes.
- Use a dedicated trace to connect the BSNS pin to the battery pack output node for accurate sensing of the battery voltage.
- Use 0603 size or 0402 size resistors and capacitors to achieve the smallest possible footprint solution on boards where space is limited.

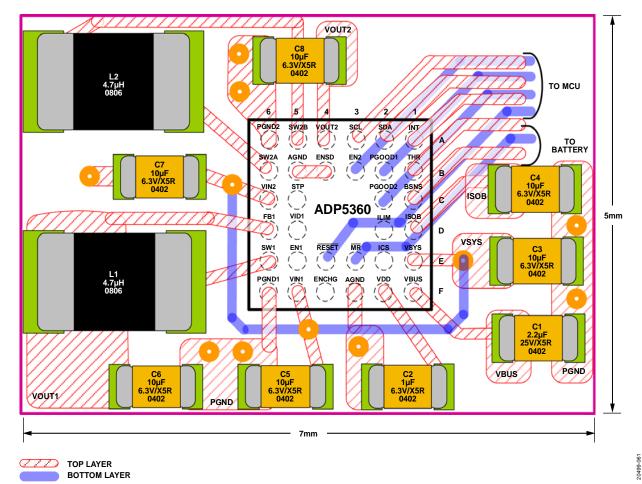


Figure 62. Recommend Layout

## FACTORY-PROGRAMMABLE OPTIONS

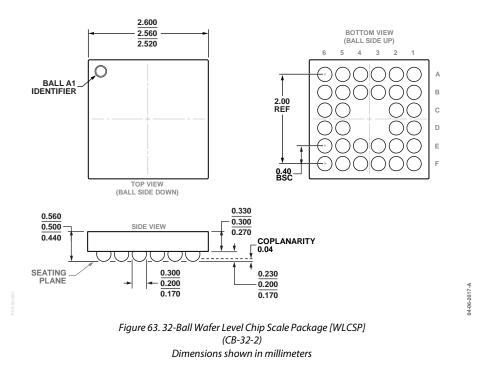
Parameter	Value	Default Setting	
I <sup>2</sup> C Address	0x46	0x46	
	0x56		
	0x66		
	0x76		
EN_CHG	Enable charger	Disable charger	
	Disable charger		
ITHR	60 μA	60 µA	
	12 μA		
	6 μΑ		
VTRM	3.96 V	4.16 V	
	4.06 V		
	4.16 V		
	4.26 V		
	4.36 V		
	4.36 V		
	4.46 V		
	4.46 V		
EN_BATPRO	Disable battery protection function	Enable battery protection function	
	Enable battery protection function		
UV_DISCH	2.2 V	2.5 V	
	2.5 V		
	2.6 V		
	2.8 V		
OC_DISCH	100 mA	600 mA	
	200 mA		
	400 mA		
	600 mA		
OV_CHG	4.25 V	4.30 V	
	4.30 V		
	4.40 V		
	4.50 V		
OC_CHG	100 mA	150 mA for the ADP5360ACBZ-1-R7 and 400 mA for	
	150 mA	the ADP5360ACBZ-2-R7	
	200 mA		
	400 mA		
EN_BUCK	Disable buck output	Enable buck output	
	Enable buck output		
BUCK_SS	1 ms	1 ms	
	8 ms		
	64 ms		
	512 ms		
BUCK_MODE	Hystersis mode	Hystersis mode	
	FPWM mode		
DISCHG_BUCK	Disable output discharge function	Disable output discharge function	
	Enable output discharge function		

Table 77, Fuse-Programmable Trim O	ptions for the Different Modes of the ADP5360
Tuble 77.1 use 1 togrammuble 111m O	phons for the Difference blocks of the fibi 5500

**Data Sheet** 

Parameter	Value	Default Setting	
VOUT_BUCK	1.0 V	1.2 V for the ADP5360ACBZ-1-R7 and 1.8 V for the ADP5360ACBZ-2-R7	
	1.2 V		
	1.5 V		
	1.8 V		
	2.5 V		
	2.8 V		
	3.0 V		
	3.3 V		
EN_BUCKBST	Disable buck boost output	Disable buck boost output	
	Enable buck boost output		
BUCKBST_SS	1 ms	1 ms	
	8 ms		
	64 ms		
	512 ms		
DISCHG_BUCKBST	Disable output discharge function	Disable output discharge function	
	Enable output discharge function		
VOUT_BUCKBST	2.5 V	3.3 V for the ADP5360ACBZ-2-R7 and 5.0 V for the ADP5360ACBZ-1-R7	
	3.3 V		
	3.6 V		
	4.0 V		
	4.2 V		
	4.6 V		
	5.0 V		
	5.5 V		
PG1_REV	Disable PGOOD1 pin output active low	Disable PGOOD1 pin output active low	
	Enable PGOOD1 pin output active low		
VBUSOK_MASK1	Do not output the $V_{VBUS}$ voltage status signal to the external PGOOD1 pin	Do not output the V <sub>VBUS</sub> voltage status signal to the external PGOOD1 pin	
	Output the $V_{VBUS}$ voltage status signal to the external PGOOD1 pin		
VOUT1OK_MASK1	Do not output the buck PGOOD signal to the external PGOOD1 pin	Do not output the buck PGOOD signal to the external PGOOD1 pin	
	Output the buck PGOOD signal to the external PGOOD1 pin		

## **OUTLINE DIMENSIONS**



## **ORDERING GUIDE**

Model <sup>1</sup>	Temperature Range	Package Description	Package Option
ADP5360ACBZ-1-R7	–40°C to +85°C	32-Ball Wafer Level Chip Scale Package [WLCSP]	CB-32-2
ADP5360ACBZ-2-R7	–40°C to +85°C	32-Ball Wafer Level Chip Scale Package [WLCSP]	CB-32-2
ADP5360CB-EVALZ		Evaluation Board Assembled with ADP5360ACBZ-1-R7	

 $^{1}$  Z = RoHS Compliant Part.

I<sup>2</sup>C refers to a communications protocol originally developed by Philips Semiconductors (now NXP Semiconductors).

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